# OICOM

# SERVICE MANUAL

•	ANSCEIVE	

Icom Inc.

#### SCOPE OF THE SERVICE MANUAL

This service manual covers all service information related to the theoretical, physical, mechanical and electrical characteristics of the IC-H18 VHF TRANSCEIVER.

#### **ASSISTANCE**

If you require assistance or further information regarding the operation and capabilities of the IC-H18, contact your nearest authorized Icom Dealer or Icom Service Center.

Address are provided on the back cover for your convenience.

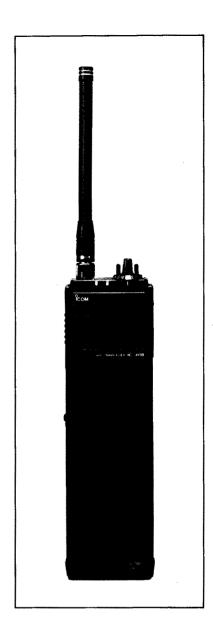
### ORDERING REPLACEMENT PARTS

For the fastest service, supply all of the following information when ordering parts from your dealer or Icom Service Center:

- 1. Equipment model and serial number
- 2. Schematic part identifier or service manual page number
- 3. Unit name and printed circuit board number (e.g., MAIN UNIT/B-1665C)
- 4. Component part number and name (e.g., 2SC2712 Transistor)
- 5. Order number for mechanical parts
- 6. Quantity required (e.g., 3pcs.)

#### REPAIR NOTE

- 1. **DO NOT** open transceiver covers until the transceiver is disconnected from a power source.
- 2. **DO NOT** force any of the variable components. Turn them slowly and smoothly.
- 3. DO NOT short any circuits or electronic parts.
- 4. An insulated tuning tool MUST BE used for all adjustments.
- DO NOT keep power ON for a long time when the transceiver is defective.
- DO NOT transmit power into a signal generator or sweep generator. Always connect a 30dB or 40dB attenuator between the transceiver and a deviation meter or spectrum analyzer when using such test equipment.
- 7. Read the instructions of test equipment thoroughly before connecting the equipment to the transceiver.



### **TABLE OF CONTENTS**

SECTION	1	SPECIFICATIONS	1 — 1
SECTION	2	OUTSIDE AND INSIDE VIEWS 2 -	<b>– 1 ∼ 3</b>
	2 - 1	OUTSIDE VIEWS	2 — 1
	2 - 2	·	2 — 2
SECTION	3	BLOCK DIAGRAM	3 — 1
SECTION	4	CIRCUIT DESCRIPTION 4 -	<b>- 1 ∼ 5</b>
	4 - 1	RECEIVER CIRCUITS	4 — 1
	4 - 2	TRANSMITTER CIRCUITS	4 — 2
	4 - 3	PLL CIRCUITS	4 — 3
	4 - 4	VOLTAGE LINES	4 — 4
	4 - 5	T5/R5 SWITCHING CIRCUIT (MAIN UNIT)	4 — 4
	4 - 6	CTCSS CIRCUIT (MAIN UNIT)	4 — 4
	4 - 7	CPU (IC801) PORT ALLOCATIONS	4 — 5
SECTION	5	MECHANICAL PARTS AND DISASSEMBLY 5 -	<b>− 1 ~ 2</b>
SECTION	6	ADJUSTMENT PROCEDURES 6 -	<b>− 1 ~ 6</b>
	6 - 1	PLL ADJUSTMENT	6 — 1
	6 - 2	RECEIVER ADJUSTMENT	6 — 3
	6 - 3	TRANSMITTER ADJUSTMENT	6 <b>—</b> 5
SECTION	7	BOARD LAYOUTS 7 -	<b>- 1 ∼ 7</b>
	7 - 1	INTERCONNECTION	7 — 1
	7 - 2	LOGIC AND EF UNITS	7 — 2
	7 - 3	MAIN UNIT	7 — 4
	7 - 4	RF UNIT	7 — 6
SECTION	8	PARTS LIST 8 -	<b>- 1 ∼ 6</b>
SECTION	9	VOLTAGE DIAGRAM	9 — 1
SECTION	10	OPTIONS INFORMATION	- 1 ∼ 2
	10 - 1	1 BM-70 AC BATTERY CHARGER	
		2 UT-42 DTMF ENCODER UNIT	

To program the operating frequency, tone frequency, etc., see the separately available EX-704 PROGRAMMING MANUAL (A-8011-1EX).

### SECTION 1 SPECIFICATIONS

#### GENERAL

Frequency range
 Type of emission
 136~174MHz
 16K0F3E

• Number of channels : Up to 16 channels

• Frequency stability : ±0.0005%

Antenna impedance : 50Ω unbalanced

Power supply voltage :

BATTERY PACK	OUTPUT VOLTAGE	
CM-71	7.2V	
CM-72	8.4 V	
CM-73	13.2V	

(Negative ground)

Usable temperature range
 ∴ -30°C ~ +60°C (-22°F ~ +140°F)
 Dimensions
 ∴ 65 mm(W) × 109 mm(H) × 35 mm(D)

 $2.6''(W) \times 4.3''(H) \times 1.4''(D)$ , (without battery pack)

• Weight : 350g (0.77 lbs), (without battery pack)

### **■** TRANSMITTER

• RF Output power (At 13.2V DC) : 5W

• Modulation system : Variable reactance frequency modulation

• Current drain (At 13.2V DC) : High power 1.8A

Low power 1.2A

Microphone impedance
 Maximum deviation
 Spurious emissions
 FM hum and noise
 2.2kΩ
 ±5kHz
 -60dB
 40dB

◆ Audio response : +1dB, -3dB of +6dB/octave from 300Hz~3000Hz

### **■ RECEIVER**

Receiver system : Double-conversion superheterodyne

• Sensitivity : 0.28 µV at 12 dB SINAD

Squelch sensitivity : 0.22μV
 Modulation acceptance : ±7kHz

• Intermediate frequencies : 1st 21.8MHz

2nd 455kHz

• Current drain (At 13.2V DC) : Audio max. 0.25 A

Standby 70 mA

Audio output power :

 BATTERY PACK
 OUTPUT POWER (at 5% distortion with an 8Ω load)

 CM-71
 200 mW

 CM-72
 350 mW

 CM-73
 500 mW

Audio output impedance : 8Ω
 Selectivity (±25kHz) : 70dB
 Spurious frequency rejection : 70dB
 Image rejection : 68dB
 Inter modulation : 70dB
 Hum and noise : 40dB

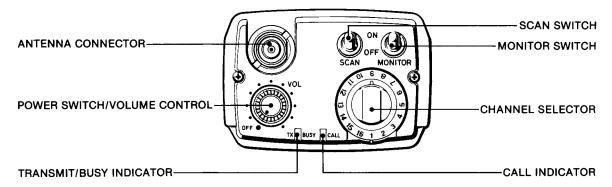
Audio response : +1dB, −3dB of −6dB/octave from 300Hz ~ 3000Hz

All specifications are per EIA RS316B procedures.

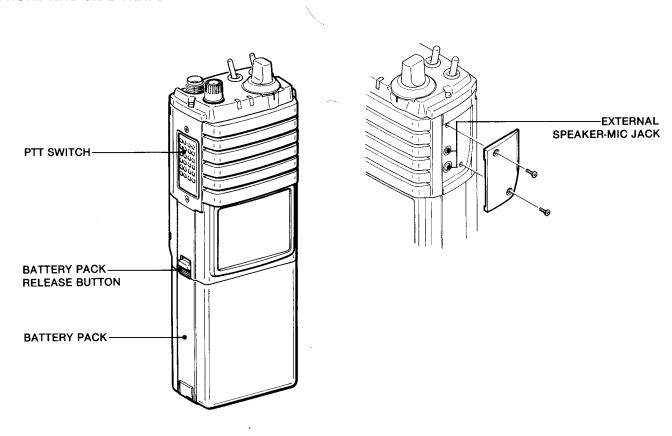
### SECTION 2 OUTSIDE AND INSIDE VIEWS

### 2-1 OUTSIDE VIEWS

#### • TOP VIEW



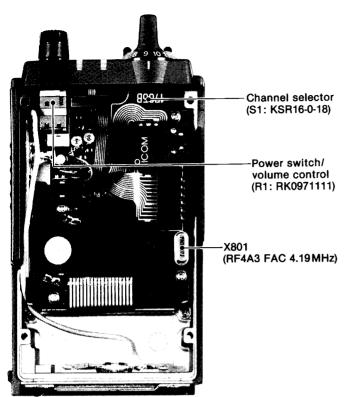
#### • FRONT AND SIDE VIEWS

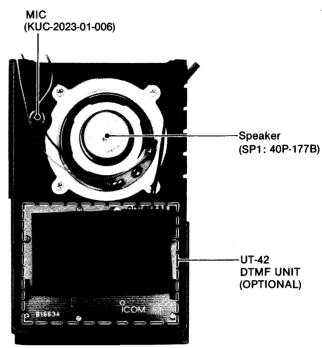


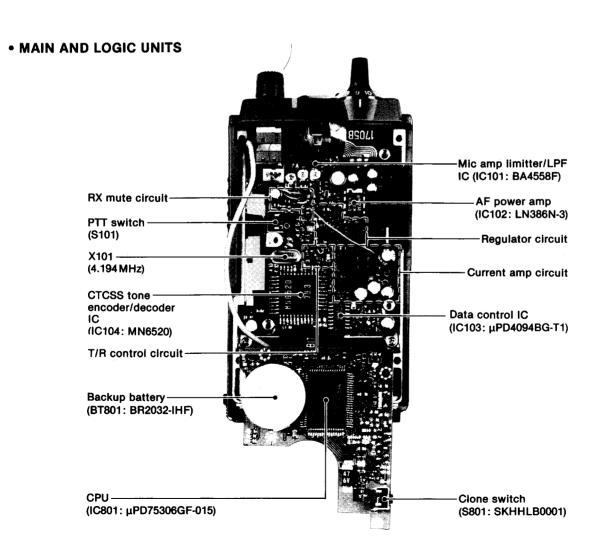
### 2-2 INSIDE VIEWS

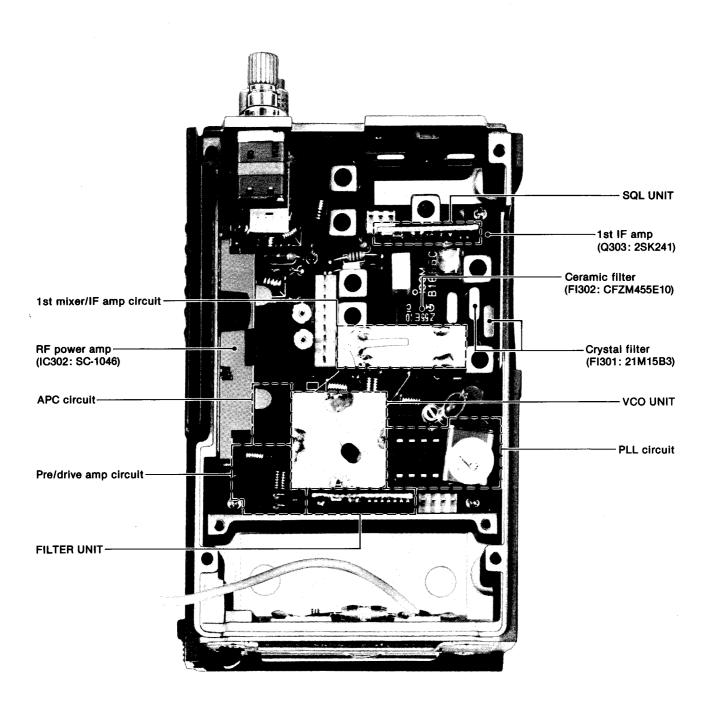
#### LOGIC UNIT

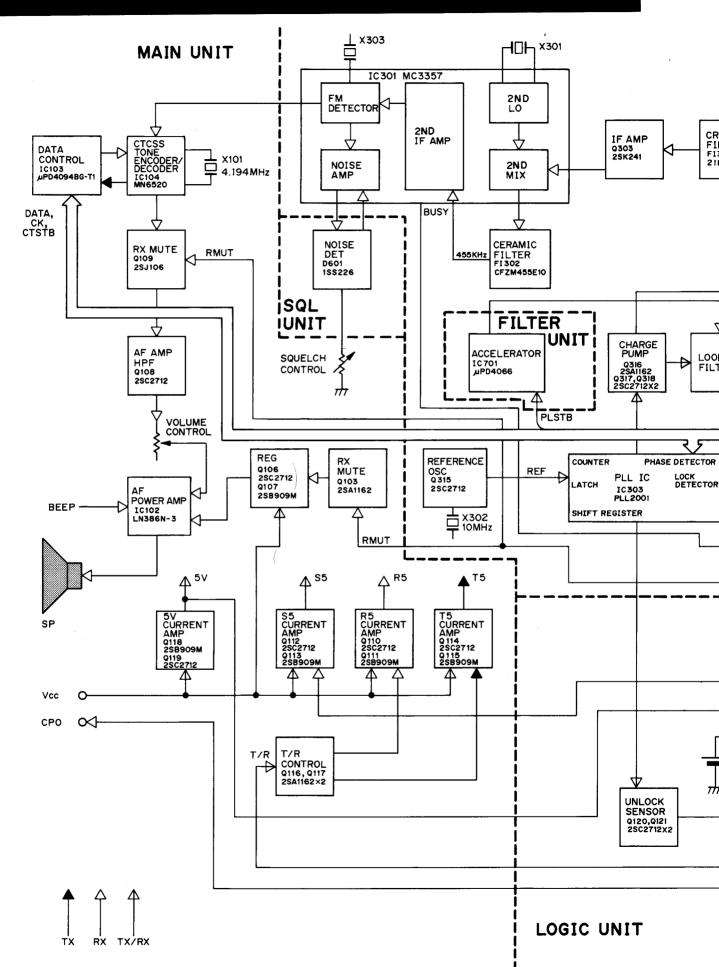
#### • FRONT PANEL (Rear side)

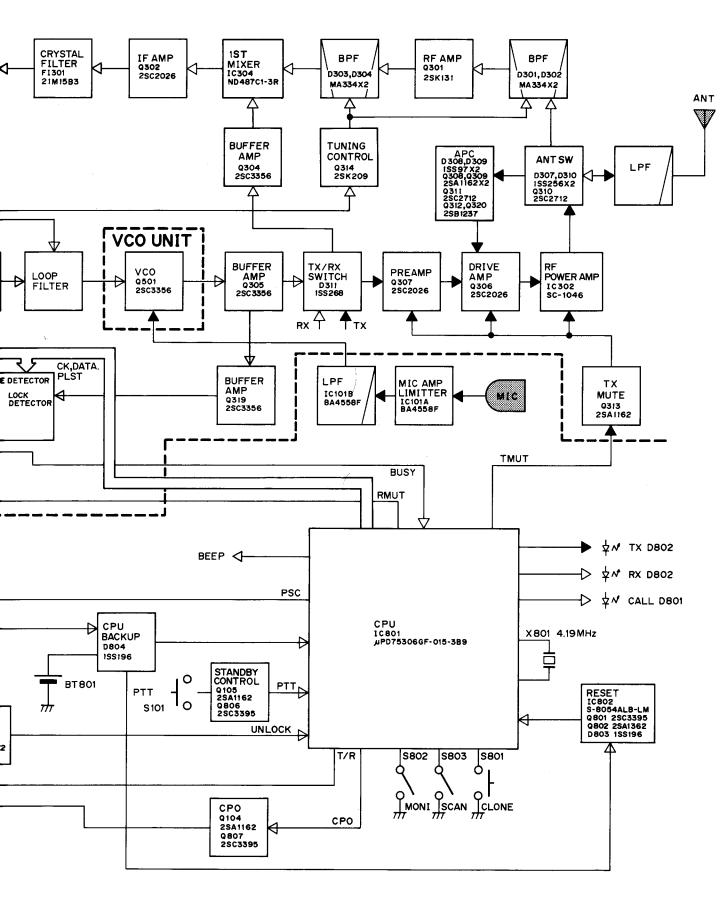












### 4-1 RECEIVER CIRCUITS

# 4-1-1 ANTENNA SWITCHING CIRCUIT (RF UNIT)

Received signals enter the antenna connector and pass through a two-stage Chebyschev low-pass filter (L311, L312, C340 $\sim$ C344). The signals are applied to the antenna switching circuit (D307, D310, L310, C337, C338), and then to the RF circuit. This antenna switching circuit employs a  $\lambda/4$ -type diode switching system.

### 4-1-2 RF CIRCUIT (RF UNIT)

The filtered RF signals are applied to the RF amplifier (Q301), and reapplied to the bandpass filter (L304, D303, D304, C309 $\sim$ C312) to suppress out-of-band signals.

### 4-1-3 1st MIXER CIRCUIT (RF UNIT)

This circuit is a double balanced mixer composed of four Schottky barrier diodes (D305). From the matching transformer (L305), the RF signals are applied to D305. The product of the 1st LO signal passes through C314 and is applied to D305. L306 outputs a 21.8 MHz 1st IF signal.

### 4-1-4 1st IF CIRCUIT (RF UNIT)

After passing through the IF amplifier (Q302) and the matching transformer (L307), the 1st IF signal is applied to the crystal filter (Fi301) to suppress out-of-band signals. The 1st IF signal is then applied to the 2nd IF circuit via L308.

# 4-1-5 2nd IF AND DEMODULATOR CIRCUITS (RF UNIT)

The 1st IF signal amplified at amplifier (Q303) passes through the matching transformer (L309).

The 1st IF signal from L309 is applied to the 2nd mixer section of IC301, and is mixed with 2nd LO signal to convert the 1st IF signal to a 455kHz 2nd IF signal. IC301 contains the 2nd mixer circuit, the 2nd LO circuit and the quadrature detector circuit. The 2nd LO circuit and X301 generate 21.345MHz for the 2nd LO signal.

The 2nd IF signal from the 2nd mixer (IC103, pin 3) passes through the ceramic filter Fl302 where unwanted signals are suppressed. It is then amplified at the limiter amplifier section (IC301, pin 5) and applied to the quadrature detector section (IC301, pin 8 and ceramic discriminator X303) to demodulate the 2nd IF signal into an AF signal.

AF signal output from pin 9 of IC301 is applied to the AF circuit.

### 4-1-6 AF CIRCUIT (MAIN UNIT)

The AF signal from IC301 is applied to pin 29 of IC104. IC104 contains the CTCSS tone encoder/decoder, the AF amplifier, and the two-stage AF filter.

Passing through the AF amplifier section and the two-stage AF filter in IC104, the filtered signal is output from pin 18. The -6dB/octave low-pass filter (R155, C153, C167) deemphasizes the signal which then passes through the muting circuit (Q109).

The AF preamplifier (Q108) amplifies the signal to a sufficient level to drive IC102. When the squelch is closed, Q109 functions as an AF mute switch. Q108 functions as both an AF preamplifier and a high-pass filter. The signal passes through the VOLUME CONTROL (R1) and is applied to the AF amplifier (IC102, pin 2).

The regulated DC voltage is applied to pin 6 of IC102 through the voltage regulator circuit consisting of Q107, Q106 and D104. In this way, IC102 should not be damaged from overloading.

# 4-1-7 SQUELCH CIRCUIT (RF AND LOGIC UNITS)

R604 and R605, connected to pin 9 of IC301, improve the temperature characteristic of the AF output power.

The internal op-amp in IC301 amplifies noise components of frequencies at 20kHz and above, and outputs the resulting signals from pin 11. Output signals are rectified by D601.

The rectified voltage triggers the squelch circuit in IC301. Pin 13 of IC301 outputs the squelch signal. The signal is applied to the CPU (IC801, pin 61) through the BUSY signal line.

The squelch circuit is activated when Q109 is turned on by a signal (RMUT) from the CPU (IC801, pin 52).

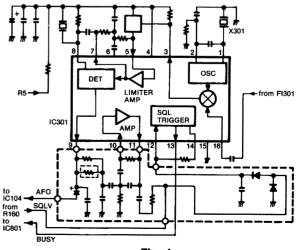


Fig. 1

### **4-2 TRANSMITTER CIRCUITS**

# 4-2-1 MICROPHONE AMPLIFIER (MAIN UNIT)

AF signals from the built-in condenser microphone are applied to IC101A at pin 3, and are pre-emphasized to 6dB/octave through C104 and R102 connected to pin 2. IC101A functions as the microphone amplifier and the limiter.

The signals pass through the splatter filter circuit (IC101B, R107, C108, R110, C109, R111, C111) where signals of 3kHz and above are attenuated. IC101 pin 7 then outputs the signals. The signals are applied to D501 in the VCO circuit as signals to be modulated.

The signals to be modulated then change the capacitance of D501 to make an FM signal.

#### 4-2-2 DRIVE AMPLIFIER (RF UNIT)

The VCO output is buffer-amplified at Q305, and applied to the transmit/receive switching circuit (D311).

After passing through the transmit/receive switching circuit (D311), and the preamplifier (Q307), the VCO output is amplified at the drive amplifier (Q306) where 20 mW is obtained.

The voltage controlled by the APC circuit is applied to the collector of Q306 for a stable RF output power from IC302.

### 4-2-3 RF POWER AMPLIFIER (RF UNIT)

IC302 is a power module which provides stable 5W output power.

RF signals from the drive amplifier (Q306) are applied to pin 1 of IC302. The amplified signals are output from pin 5, and applied to the ANTENNA CONNECTOR through the APC detector circuit, the antenna switching circuit and the low-pass filter circuit.

### 4-2-4 APC CIRCUIT (RF UNIT)

The APC detector circuit consists of L315, C352, C353, R324, R325, D308 and D309.

When the antenna impedance is matched at  $50\Omega$ , the voltage detected at D308 and D309 is at a minimum.

The voltage detected at D308 and D309 is applied to the differential amplifier (Q308, Q309). The APC reference voltage is applied to the base of Q309.

When the antenna impedance is mismatched, the base voltage of Q308 is higher than the reference voltage. The collector voltage of Q308 decreases. Q311 amplifies the current from the differential amplifier which controls Q312 and Q320—changing the supply voltage to Q306 and IC302.

This decreases the output power of the drive amplifier (Q306) and power amplifier (IC302) until the base voltage of Q308 becomes equal to the base voltage of Q309.

# 4-2-5 POWER OUTPUT CONTROL CIRCUIT (RF UNIT)

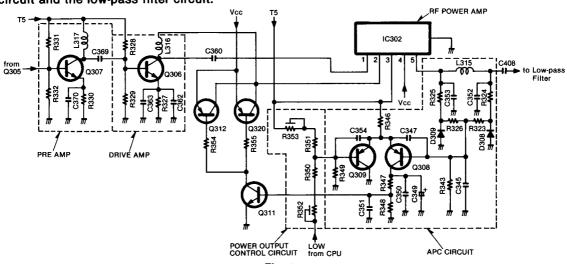
The power output control circuit consists of R349 $\sim$  R353. This circuit controls the RF output power with the APC reference voltage.

When HIGH output power is selected, RF output power can be adjusted with R353.

When LOW output power is selected, the signal for low power selection from the CPU (IC801) is applied to R352 through the LOW signal line. RF output power is adjusted with R352.

#### 4-2-6 TX MUTE CIRCUIT (RF UNIT)

"TMUT" signal from the CPU (IC801) turns Q313 OFF. Bias voltages to Q307, Q306 and IC302 are cut off, stopping transmission.



# 4-2-7 ANTENNA SWITCHING CIRCUIT (RF UNIT)

When transmitting, Q310, D307 and D310 are turned on. L310 and C338 form a parallel resonant circuit. The RF output signal from IC302 is not applied to receiver circuit, but passes through L315, D307 and C339, the low-pass filter (L311, L312, C340~C344) and then on to the antenna. The impedance of the parallel resonant circuit increases. Signals which leak through the resonant circuit are bypassed through D310 and Q310.

### 4-3 PLL CIRCUITS

#### 4-3-1 GENERAL

The PLL circuit, using a direct programmable divider (IC303), is designed in a way that allows the desired frequency to be generated directly at the VCO circuit. IC303 sets the dividing ratio based on serial data from the CPU (IC801), and compares the phases of the VCO signal and the reference oscillator frequency. It detects the out of step phase and outputs it.

# 4-3-2 REFERENCE OSCILLATOR CIRCUIT (RF UNIT)

A reference frequency is acquired by Q315 and X302. D313, R361 and R364 provide frequency control. Thus, the output frequency of this circuit is stable over a wide temperature range.

# 4-3-3 CHARGE PUMP AND LOOP FILTER CIRCUITS (RF UNIT)

Phase-detected signals from pins 5 and 12 are converted to DC voltage by the charge pump Q316 $\sim$  Q318; and a lag-lead loop filter consisting of R701, R702, R705 and C702.

VCO oscillating signals are controlled by a varactor diodes (D502, D503). DC voltage (PLL lock voltage) is provided through the loop filter.

D701 is used as an accelerator to ensure rapid PLL lock-up time.

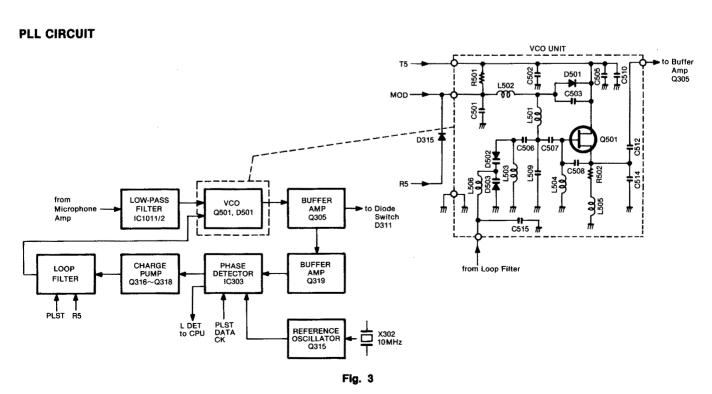
On the other hand, the output of the loop filter passes through Q314, and is used as the voltage for controlling the bandpass filter (D301~D304) of the receiver RF circuit.

### 4-3-4 UNLOCK CIRCUIT (MAIN UNIT)

When the PLL circuit is unlocked, pin 7 of IC303 is "LOW." A "LOW" signal is applied to the unlock circuit consisting of Q120 and Q121. The unlock circuit outputs the resulting signal to the CPU (IC801) pin 62.

### 4-3-5 VCO CIRCUIT (RF UNIT)

D501 changes the inductive reactance of the Clapp oscillator (Q501), shifting the receive and transmit frequencies. Varactor diodes (D502, D503) provide frequency control. The buffer amplifier (Q305, Q319) is unaffected by VCO oscillation.



### 4-4 VOLTAGE LINES

LINE	DESCRIPTION
Vcc	This voltage is applied to Q316, Q317, the 5V regulator circuits and IC102 through the fuse F1 and POWER SWITCH.
	The line voltage changes depending on type of the battery pack. 7.2V (CM-71), 8.4V (CM-72), 13.2V (CM-73).
+5V	The regulator circuit consisting of Q118, Q119,
ru V	D111 and D112 supplies 5V with low noise.
	This circuit applies a continuously stable outpu voltage in any mode because the circuit is constructed using a complementary connection ensuring high current amplification and good temperature characteristics.
<b>S</b> 5	The circuit is constructed by Q112, Q113 and D109 as a complementary circuit. When the power saver is turned on, CPU (IC801, pin 50) cuts off the S5 line intermittently to save power.
T5	Transmit 5V. Q115 supplies T5V when pin 51 o IC801 (CPU) outputs "LOW."
R5	Receive 5V. Q111 supplies R5V when pin 51 or IC801 (CPU) outputs "HIGH."

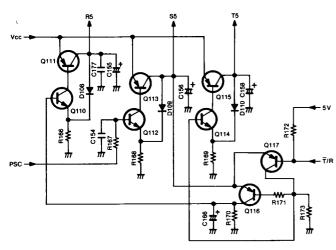


Fig. 4

# 4-5 T5/R5 SWITCHING CIRCUIT (MAIN UNIT)

When transmitting, pin 51 of IC801 (CPU) becomes "LOW." Q117 is turned ON, and Q116 is turned OFF. Bias voltage is applied to Q114, and Q115 outputs 5V as T5V.

When receiving, pin 51 of IC801 (CPU) becomes "HIGH," Q117 is turned OFF, and Q116 is turned ON. Bias voltage is applied to Q110, and Q111 outputs 5V as R5V. Because Q116 applies the voltage from the S5 line, R5 line voltage becomes zero, reducing current consumption when the power save function is ON.

### **4-6 CTCSS CIRCUIT (MAIN UNIT)**

IC104 is a programmable CTCSS tone encoder/decoder which generates 37 tone frequencies. IC801 (CPU) outputs the serial data through IC103 to set the CTCSS tone frequency at IC104 through IC103. IC104 pins 3~8 (S0~S5) receive data for the tone frequency.

When transmitting, pin 12 of IC104 becomes "LOW." When receiving, pin 12 becomes "HIGH."

#### **CTCSS TONE FREQUENCIES:**

OUTPUT	l.	IC104 INPUT PIN NU				R
FREQUENCY [Hz]	3	4	5	6	7	8
67.0	Н	L	Н	Н	Н	L
71.9	L	L	Н	Н	Н	L
74.4	Н	Н	L	Н	Н	L
77.0	L	Н	L	Н	Н	L
79.7	Н	L	L	Н	Н	L
82.5	L	L	L	Н	Н	L
85.4	Н	Н	Н	L	Н	L
88.5	L	Н	Н	L	Н	L
91.5	Н	L	Н	L	Н	L
94.8	H	L	L	Н	Н	Н
100.0	L	L	L	Η	Н	H
103.5	Н	Н	Н	٦	Н	H
107.2	L	Τ	Н	L	Н	Н
110.9	H	ال	Н	L	Н	Н
114.8	L	٦	Н	L	Н	Н
118.8	Н	Н	L	L	H	H
123.0	L	Н	٦	L	Η	Н
127.3	Ι	L	L	L	Н	Н
131.8	L	L	L	L	Н	Н
136.5	Н	Ι	Н	H	L	Н
141.3	٦	Н	Н	H	L	Н
146.2	Н	٦	H	H	L	Н
151.4	L	٦	H	H	٦	Н
156.7	Н	Ξ	اد	Ϊ	٦	Н
162.2	٦	Н	L	Н	L	Н
167.9	Н	L	٦	Н	L	Н
173.8	L	L	L	Н	L	Н
179.9	Н	Н	Н	L_	L	Н
186.2	L	Н	Н	L	L	Н
192.8	Н	L	Н	L	L	Н
203.5	L	L	Н	L	٦	Н
210.7	Н	H	L	L	L	H
218.1	L	Н	L	L	L	Н
225.7	I	L	L	L	L	Н
233.6	L	L	L	L	L	Н
241.8	H	Н	Н	Н	Н	L
250.3	L	Н	Н	Н	Н	L

### 4-7 CPU (IC801) PORT ALLOCATIONS

### INPUT PORT

INFU	PONI			
PIN	PORT	NAME	DESCRIPTION	
38	P00	INT4	Interrupt input. HIGH: Normal operation. LOW: Standby mode.	
41	P03	HIGH/LOW	HIGH: Low RF output is selected.  LOW: High RF output is selected.	
42	P10	PTT	LOW: PTT switch is pushed.	
43	P11	CLONE	The CPU enters the cloning mode when the port is "LOW."	
44	P12	MONI	The CPU turns the CTCSS OFF when the port is "LOW."	
45	P13	SCAN CONTROL	Scan starts when the port is "LOW."	
	P40~P43		Matrix input.	
60	P60	DET	The CPU reads that the same tone frequency is received when the port is "HIGH."	
61	P61	BUSY	The CPU reads that the squelch opens when the port is "HIGH."	
62	P62	UNLOCK	The CPU reads that the PLL is unlocked when the port is "LOW."	

### **OUTPUT PORT**

PIN	PORT	NAME	DESCRIPTION
34	P50	KS4	Matrix signal output. (Matrix is used for CH selection.)
35	P51	KS5	Matrix signal output.
36	P52	LOWO	Power control signal output. Outputs "LOW" when the transceiver is programmed for low power output.
37	P53	TMUT	Transmit mute output.
39	P01	СК	Clock output for serial data.
40	P02	DATA	Serial data output.
46	P20	BEEP	Outputs a 1 kHz pulse when a beep is emitted over the speaker.
47	P21	PLSTB	Strobe signal output for the PLL.
48	P22	СТЅТВ	Strobe signal output for the CTCSS tone encoder/decoder.
49	P23	TONEC	2-tone control signal output. Becomes "LOW" when DPL or SINGLE tone is selected.
50	P30	PSC	Power save control output. Becomes "LOW" when the power save function is activated.
51	P31	T/R	Transmit/Receive switching output. Becomes "LOW" with input when transmitting.
52	P32	RMUT	Receiver mute output. Becomes "HIGH" when receiver audio output is muted.
53	P33	CALLO	Busy signal outut. Outputs a signal synchronized with the BUSY input. Directly drives the TRANSMIT/BUSY INDICATOR.
63	P63	CPO	CLONE DATA output.
	P70~P73		Matrix signal output pins.

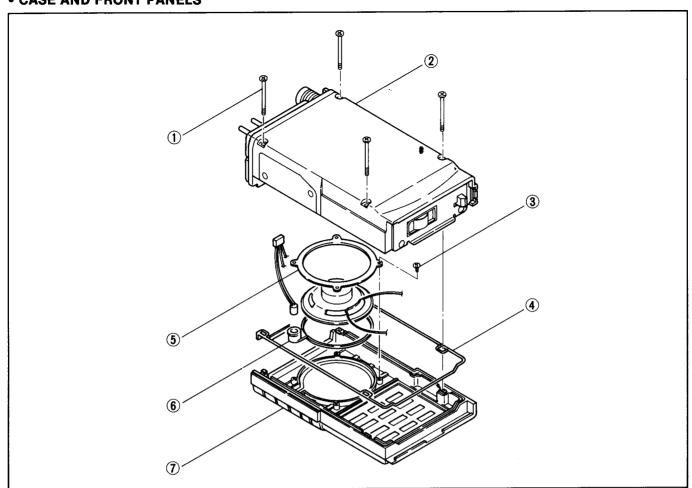
### SECTION 5 MECHANICAL PARTS AND DISASSEMBLY

LABELLED NUMBER	DESCRIPTION	ORDERING NUMBER	QTY.
0	PH B0 2×31.5 ZK	8810004000	4
②	Rear panel	8010007230	1
3	PH B0 2×4	8810000980	4
4	Casing seal	8010007240	1
<u> </u>	Speaker plate	8930012480	1
6	Speaker seal	8930012630	1
0	Front panel (A)	8210003170	1
8	Knob (channel) N-132 (includes HLH M3×3)	8610004300 (8810003520)	1 1
9	No. 0-1 PH M2×7 ZK	8810005100	1
<u></u>	Knob (Power/Volume) N-133	8610004310	1
0	Top panel	8210003180	1
12	Top panel seal	8930012560	1
(3)	PH M2×6 ZK	8810004860	2
13	Lens	8930012600	1
15	No. 0-1 PH M2×2.5	8810004870	2
16	Top plate	8310012090	1
17	Antenna connector TNC-R107 (includes nut)	6510007250	1
18	No. 0-1 PH M2×2.5	8810004870	1
19	VR nut (E)	8830000550	1
<b>20</b>	Switch seal	8310012280	1
<b>1</b>	PH M2×6	8810000030	2
20	Switch plate	8930012500	1
<b>3</b>	PTT button	8930012570	1
<b>3</b>	No. 0-1 PH M2×5 ZK	8810000530	2
25	PTT holder	8930012590	1
26	PH M2×3	8810004210	4
Ø	PH M2×3 ZK	8810005090	2
23	Side plate	8930012580	1
29	Jack cover seal	8930012620	1
<b>3</b> 0	Standoff (AR)	8930012510	3
<b>(3)</b>	No. 0-1 PH M2×2.5	8810004870	3
<b>3</b> 2	PH M2×3	8810004210	4
<b>3</b> 3	PH M2×6	881000030	1
39	Module mounting plate	8930012490	1
<b>3</b> 9	Screw lug M2	886000010	2
<b>3</b> 6	Spring (K)	8930012640	1
<b>3</b>	Release button	8930012610	1
<b>3</b> 8	BH M2×6 Ni	8810002580	2
39	Sliding guide (A)	8010007180	1
40	FH M2×4 Ni	8810002310	4
40	Connection spring	8930005980	1
<b>42</b>	Contact holder	8930011880	1

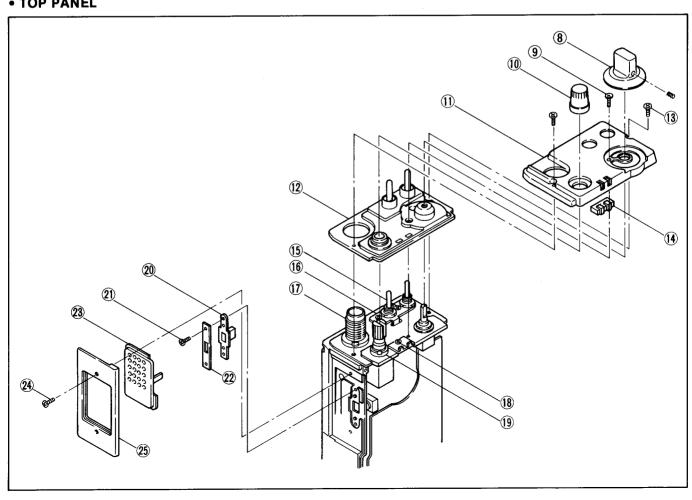
Screw type Screw: M2×6, etc. Self-tapping screw: B0 2×4, etc. Precision type screw: No. 0-1

Screw head style PH: Pan head BH: Button head FH: Flat head HLH: Headless hex head

### • CASE AND FRONT PANELS

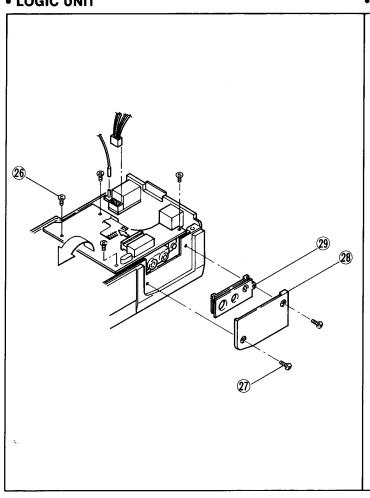


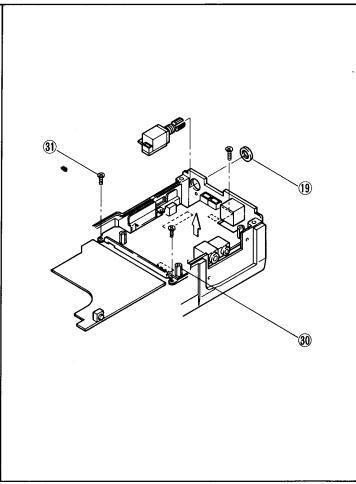
### • TOP PANEL



### • LOGIC UNIT

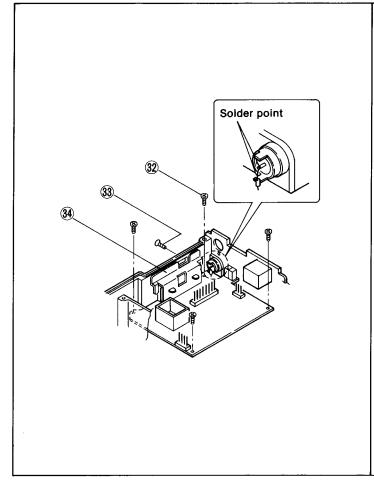
### • MAIN UNIT

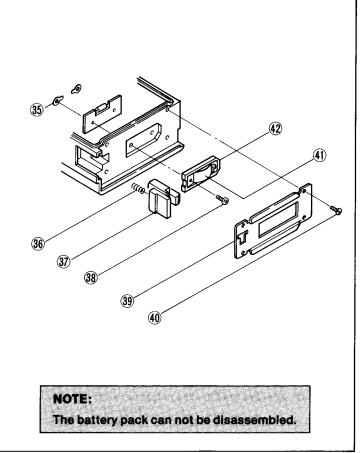




### • RF UNIT

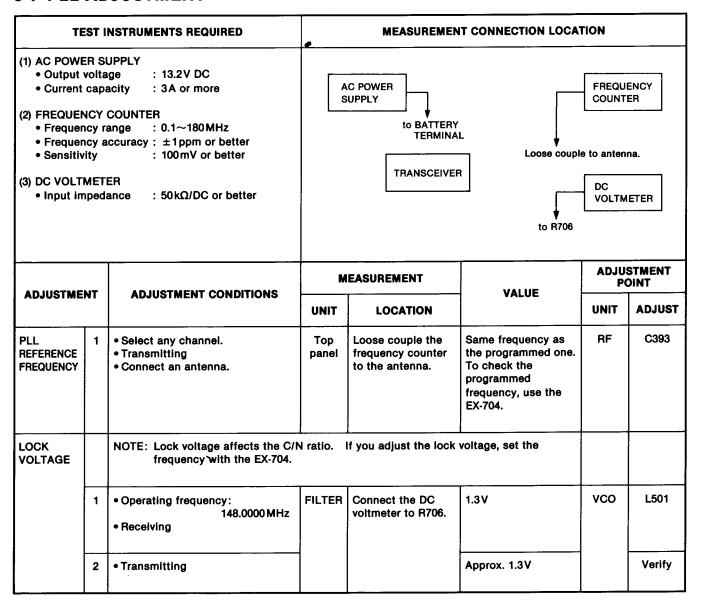
### • CONTACT HOLDER



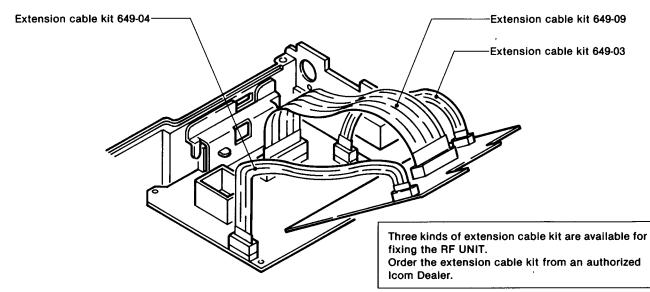


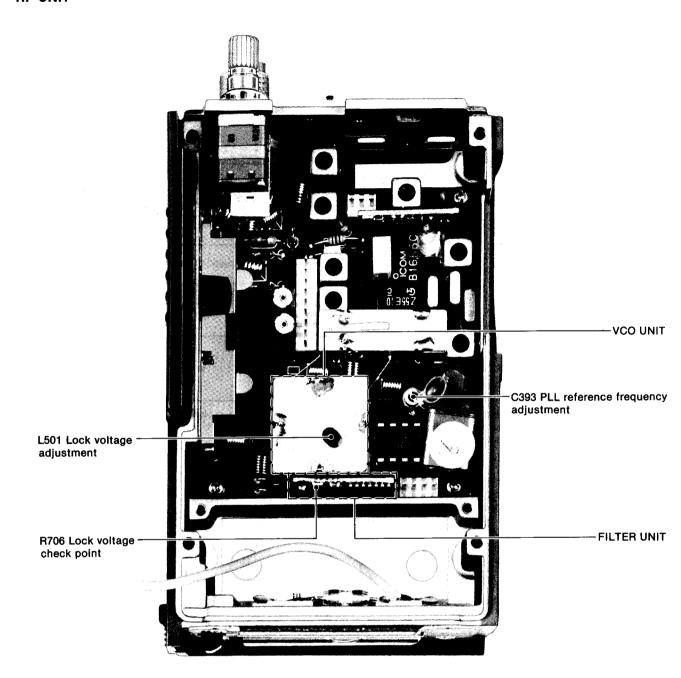
### SECTION 6 ADJUSTMENT PROCEDURES

### 6-1 PLL ADJUSTMENT

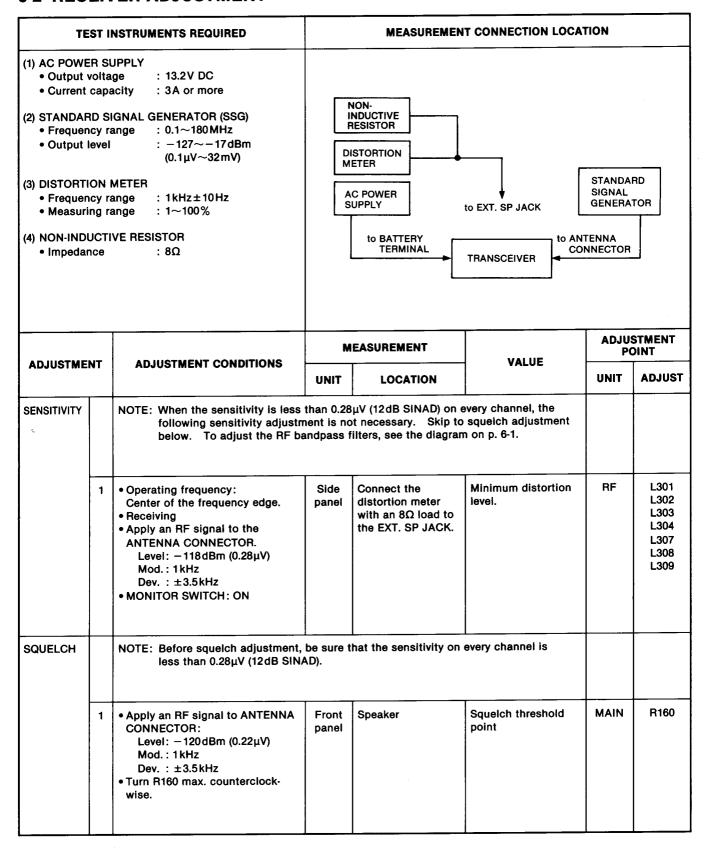


#### RF AND MAIN UNITS SEPARATION

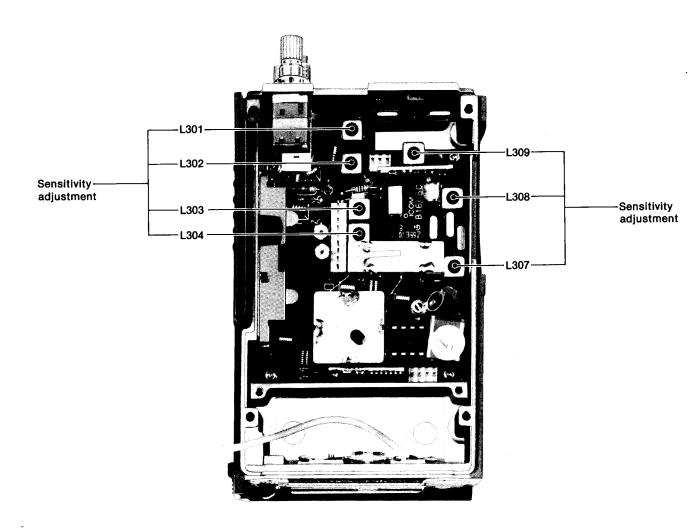




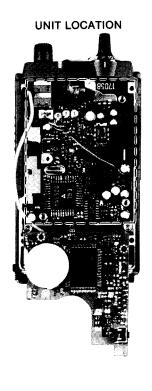
### **6-2 RECEIVER ADJUSTMENT**

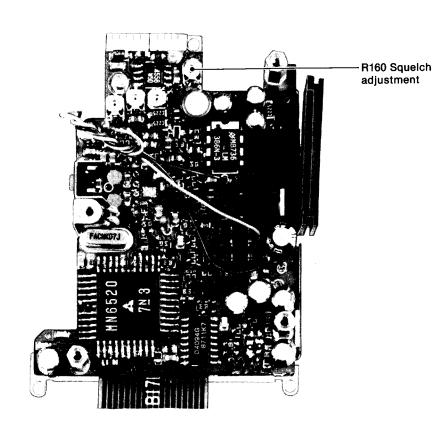


### **RF UNIT**



### **MAIN UNIT**





### **6-3 TRANSMITTER ADJUSTMENT**

(4) AC MILLI-VOLTMETER

(5) FM DEVIATION METER

• Measuring range : 2~200 mV

Frequency minimum: 480 MHz
Measuring range : 0~±5kHz

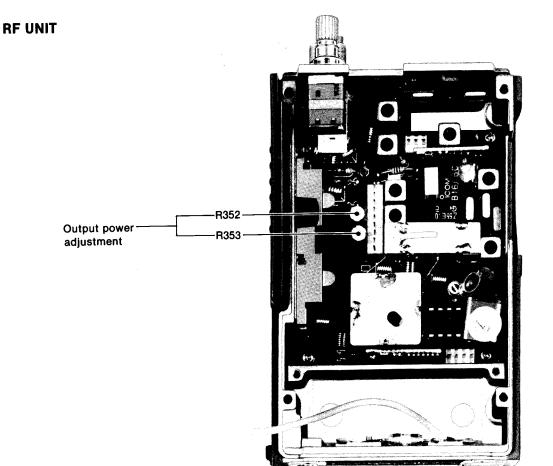
#### **MEASUREMENT CONNECTION LOCATION TEST INSTRUMENTS REQUIRED** (1) AC POWER SUPPLY Output voltage : 13.2V DC Current capacity : 3A or more FM (2) RF POWER METER (TERMINATED TYPE) DEVIATION **GENERATOR** Measuring range : 1~10W **METER** • Frequency range : 120~180 MHz AC MILLI-ATTENUATOR: • Impedance : 50Ω : Less than 1.2:1 more than 40dB **VOLTMETER** • SWR to EXT. MIC JACK (3) AF GENERATOR (AG) **RF POWER** • Frequency range : 200~2000 Hz **METER** AC POWER Output level : 0~200mV

SUPPLY

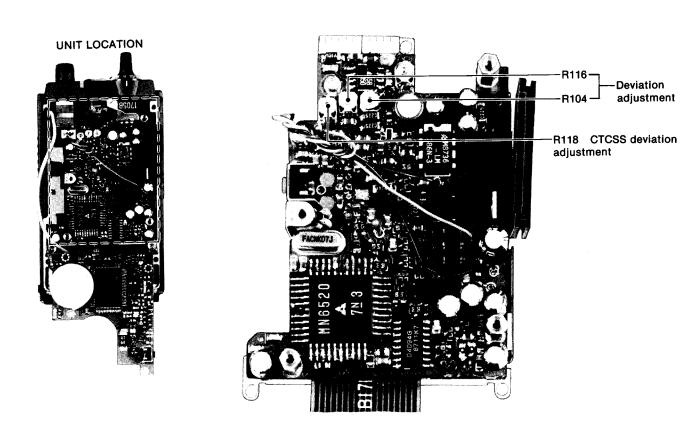
to BATTERY TERMINAL to ANTENNA CONNECTOR

TRANSCEIVER

ADJUSTMENT		AR WATERFUL COMPLETIONS	N	IEASUREMENT		ADJUSTMENT POINT	
		ADJUSTMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUST
OUTPUT POWER	1	Select any channel.     Transmitting	Top panel	Connect the RF power meter to the ANTENNA CONNECTOR.	5.0 W	RF	R353
•	2	CHANNEL SELECTOR:     Low power channel, if programmed.			1.5W		R352
DEVIATION	/IATION 1 • Select any channel • Apply an AF signal to the EXT. MIC JACK.: 1kHz/170mV • Transmitting • FM deviation meter		Top panel	Connect the FM deviation meter to the ANTENNA CONNECTOR via the attenuator.	±4.3kHz	MAIN	R116
	2	HPF : OFF LPF : 20kHz Deemphasis : OFF Deviation sense: (P-P)/2			Symmetrical deviation		R104
CTCSS DEVIATION	1	CHANNEL SELECTOR: Tone encoder programmed channel, if programmed. Apply no AF signal to the EXT. MIC JACK. Tranmitting	Top panel	Connect the FM deviation meter to the ANTENNA CONNECTOR via the attenuator.	±0.75kHz	MAIN	R118

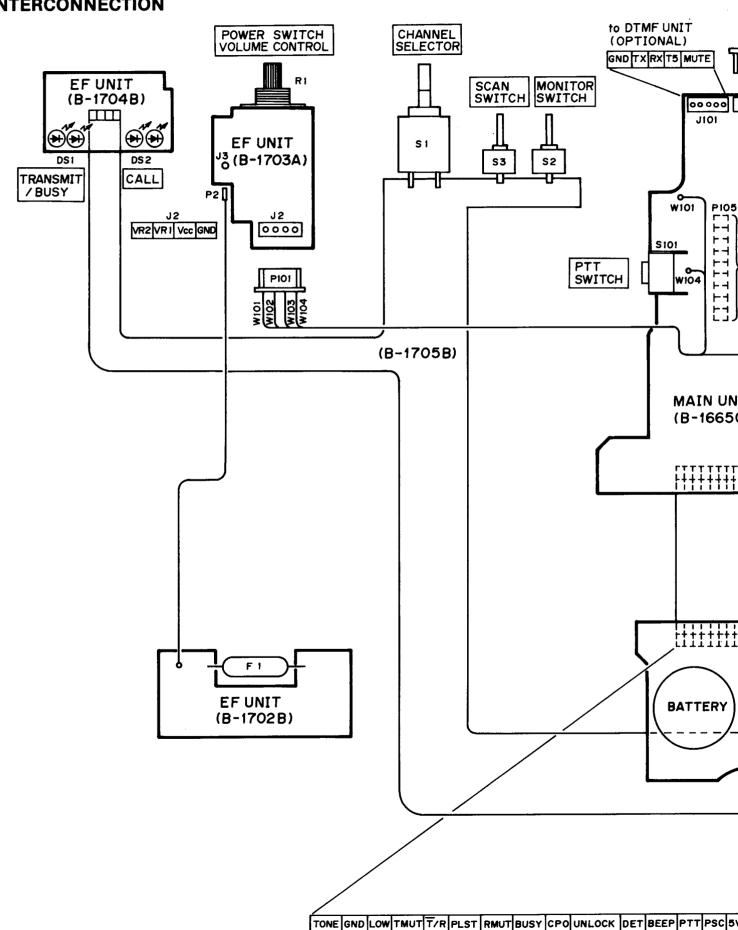


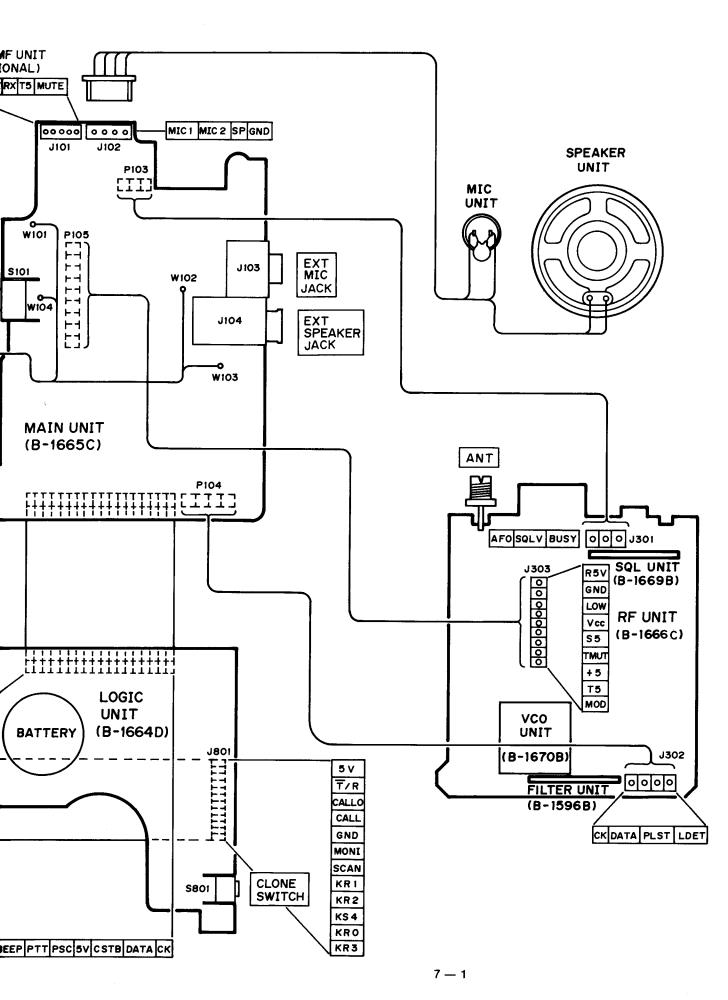
### **MAIN UNIT**



#### **BOARD LAYOUTS** SECTION 7

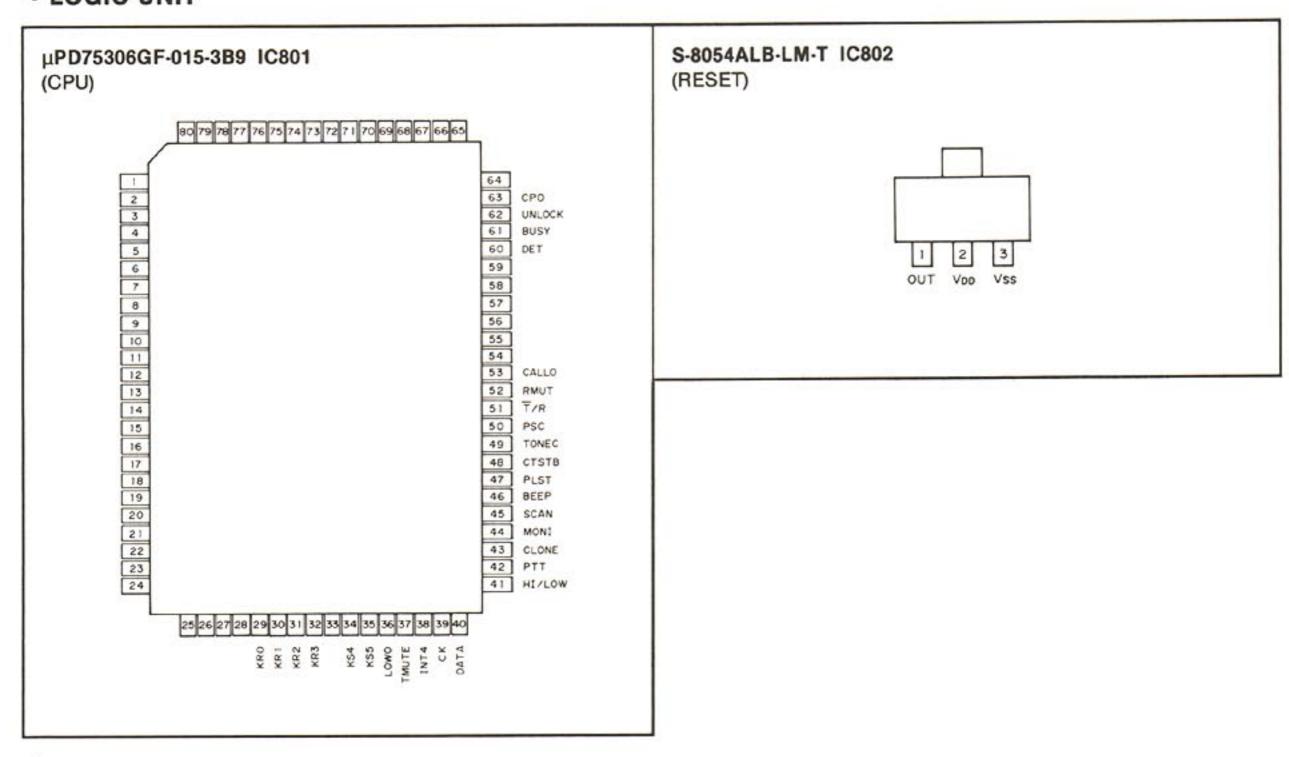
### 7-1 INTERCONNECTION





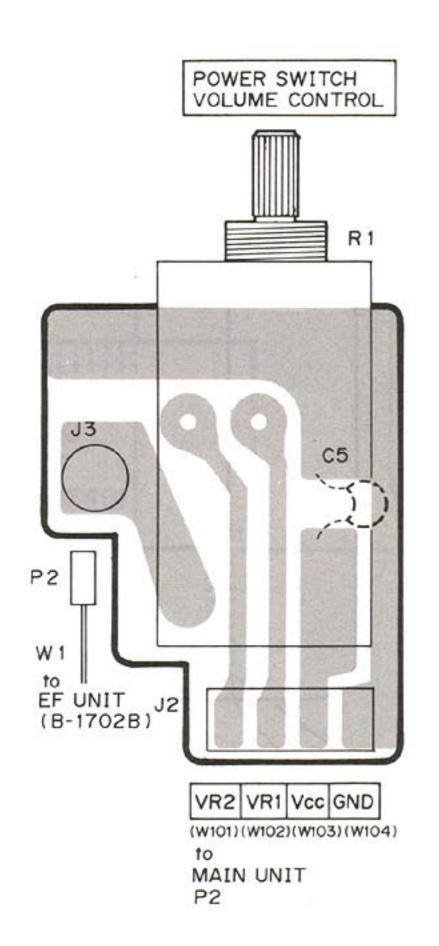
# 7-2 LOGIC AND EF UNITS

### LOGIC UNIT

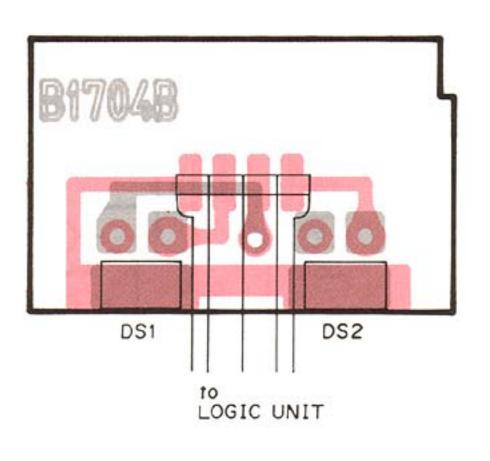


### EF UNIT

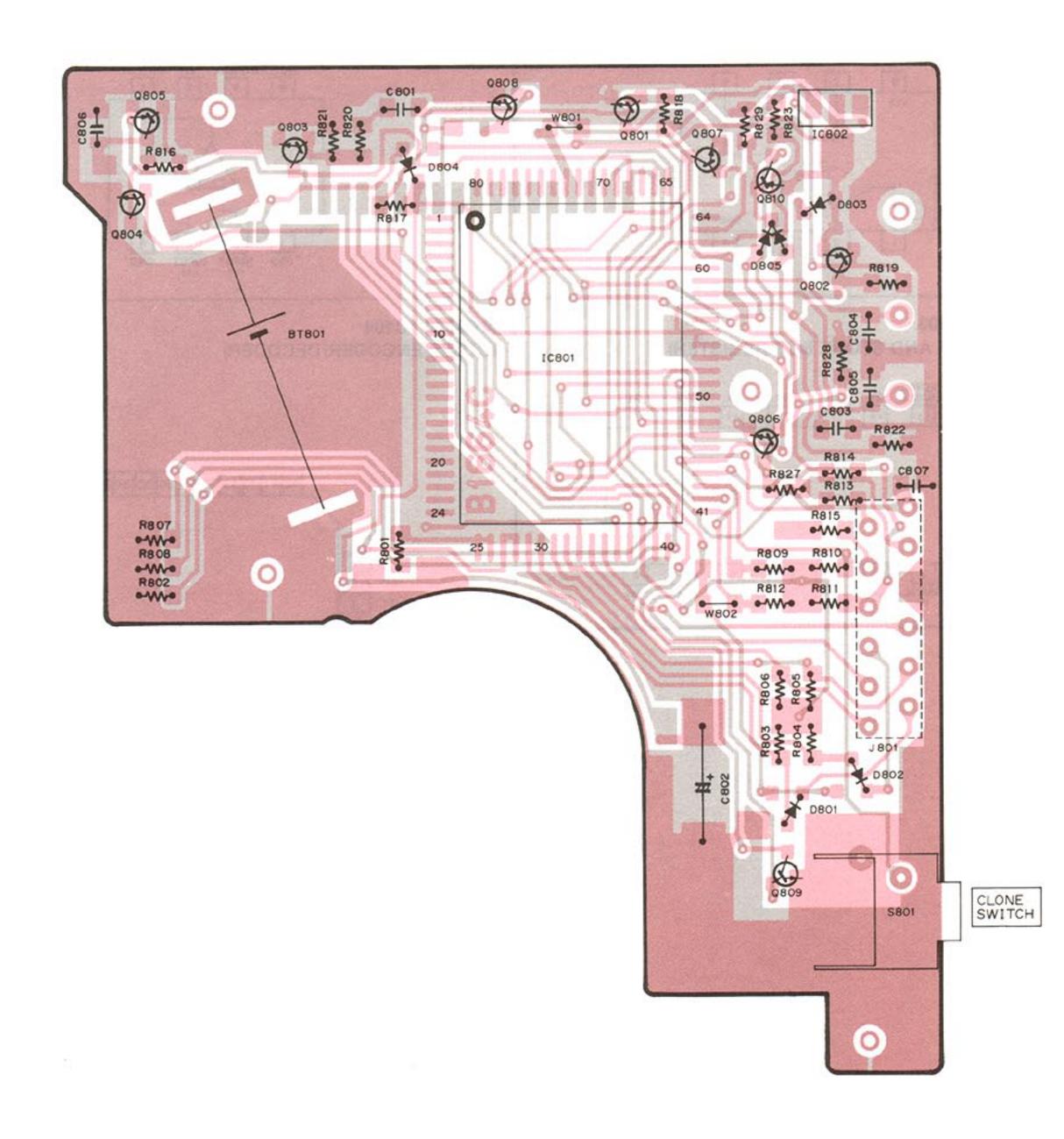
VOL

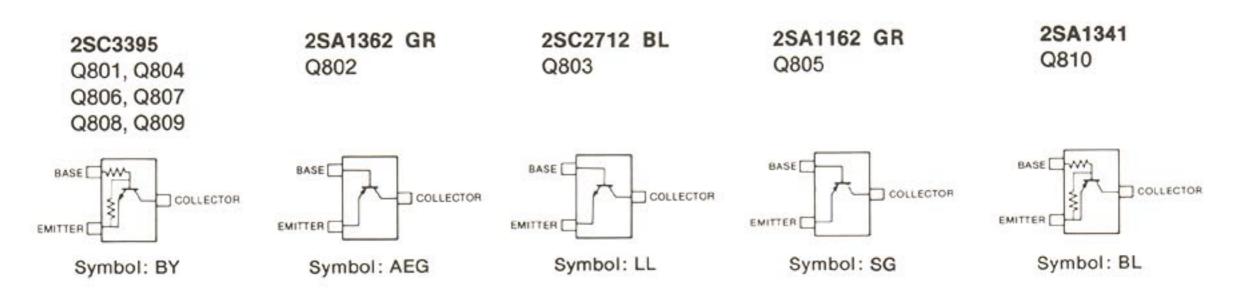


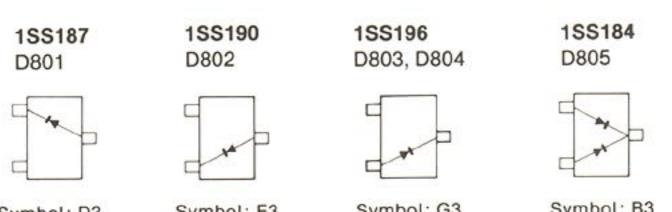
LED



### COMPONENT SIDE





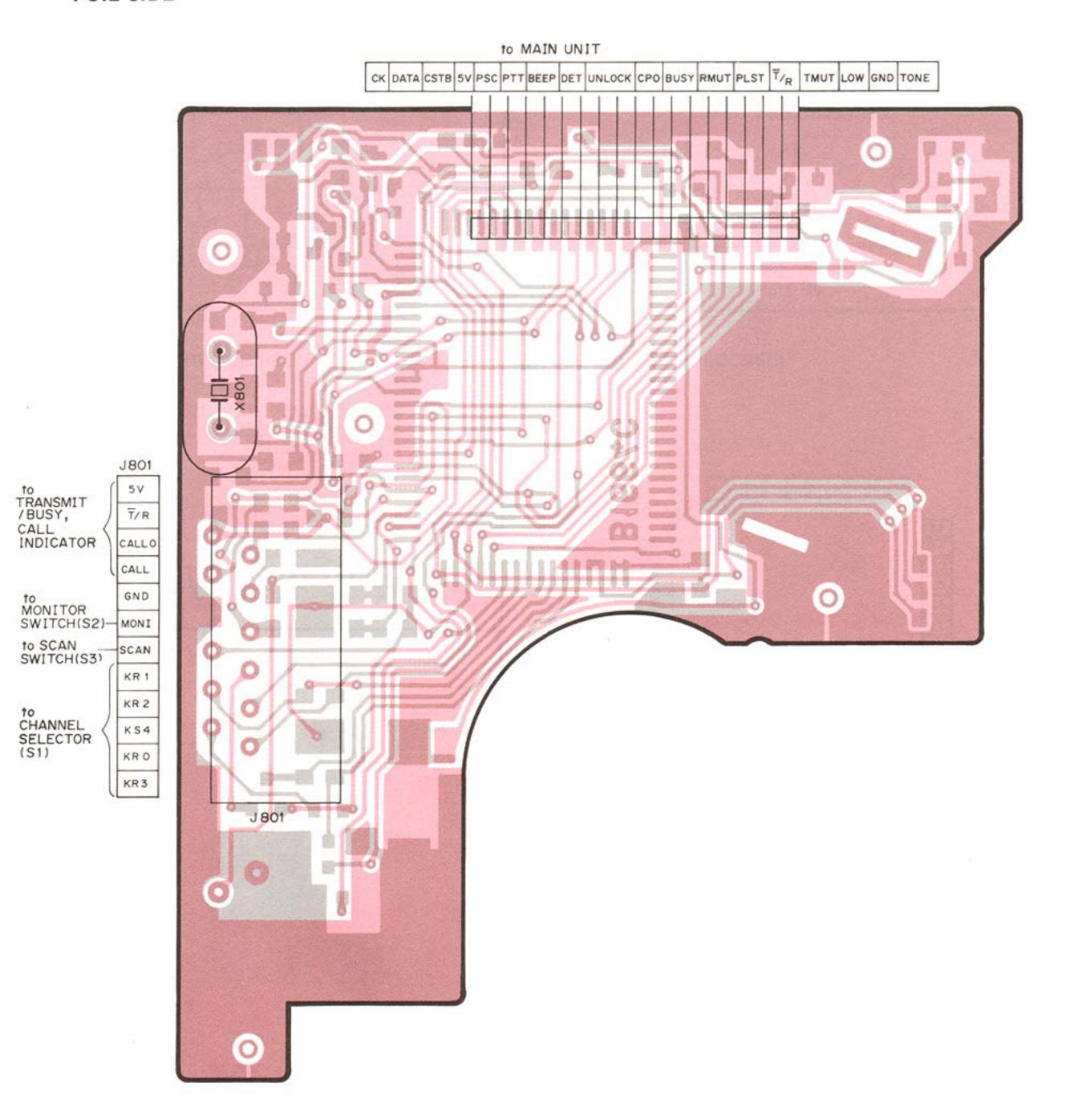


Symbol: D3

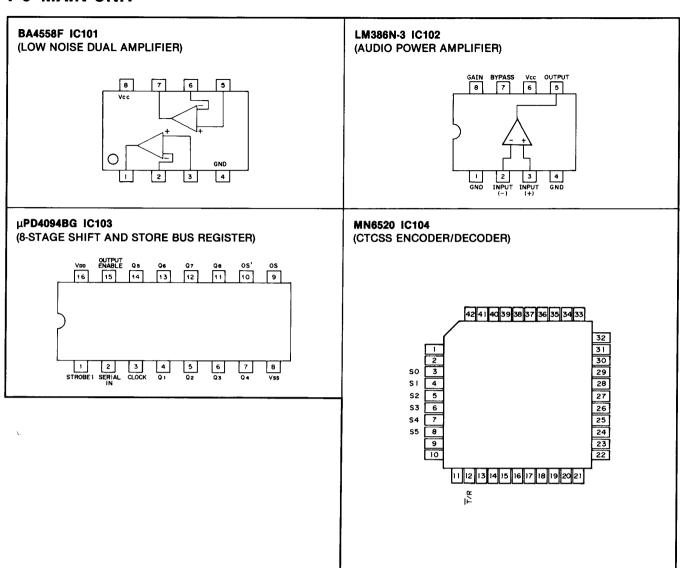
Symbol: E3

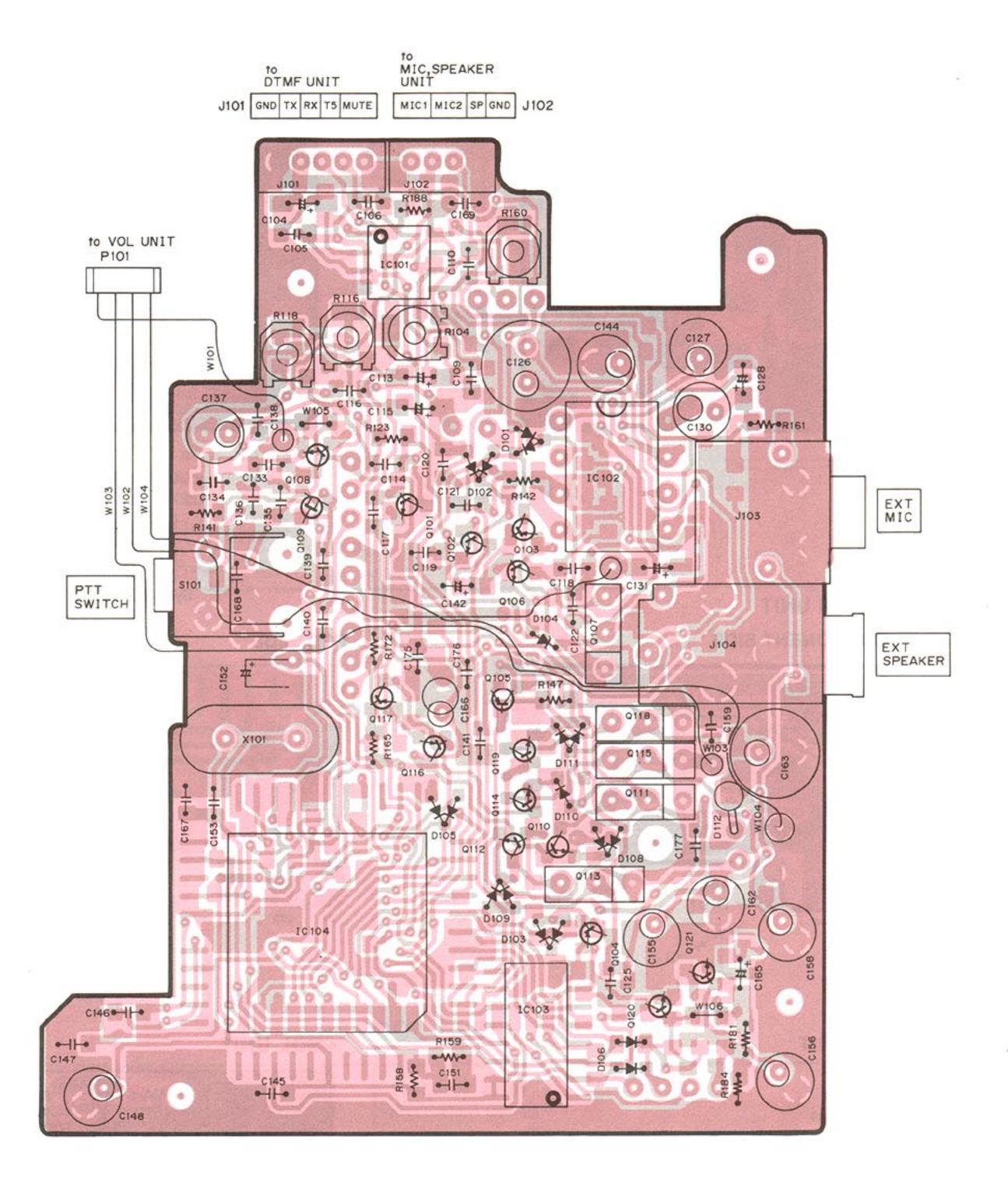
Symbol: G3

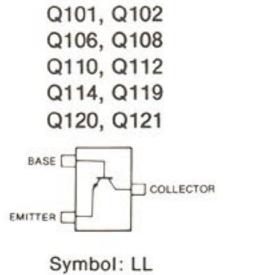
Symbol: B3



### 7-3 MAIN UNIT







2SC2712 BL

BASE COLLECTOR

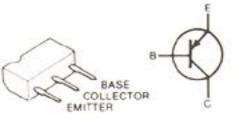
2SA1162 GR

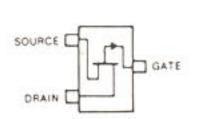
Q103, Q104

Q105, Q116

Q117

2SB909M R Q107, Q111 Q113, Q115 Q118

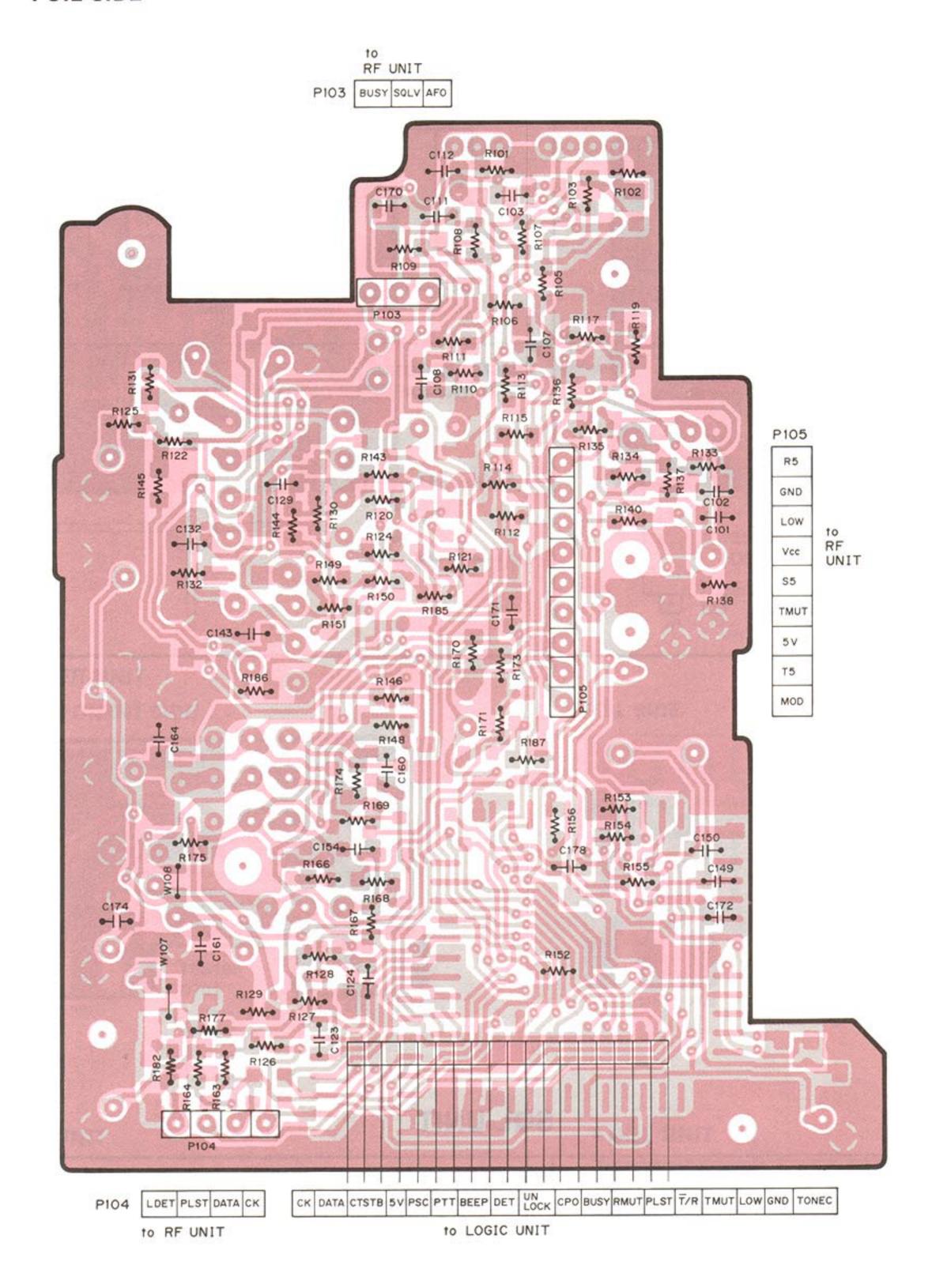




2SJ106 Y

Q109

Symbol: SG Symbol: VY

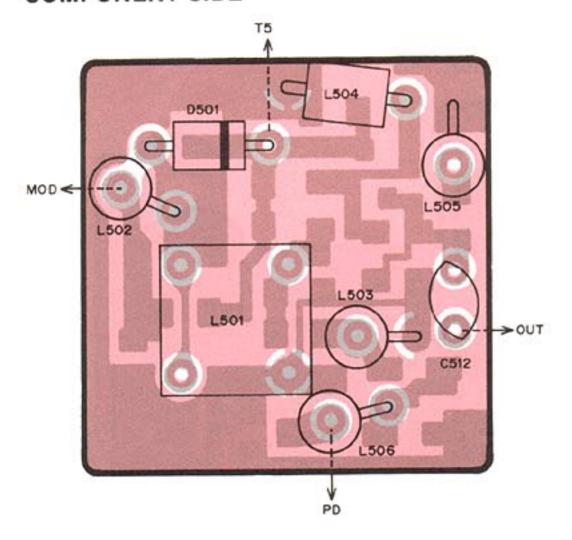


**1SS181 1SS190 RD4.7M B3 DWA010 1SS184 1SS226** D110 D111 D104 D106 D102, D103 D101 D105, D108 D109 Symbol: A3 Symbol: E3 Symbol: W8 Symbol: B3 Symbol: 473 Symbol: C3

### 7-4 RF UNIT

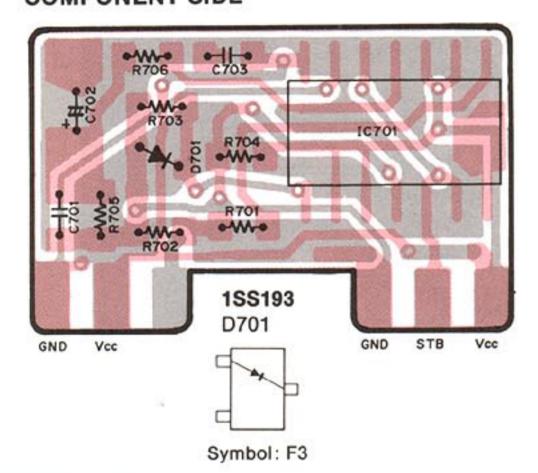
### VCO UNIT

### COMPONENT SIDE

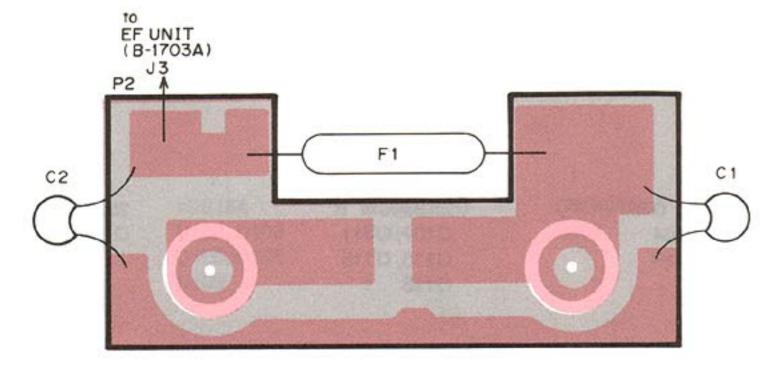


FILTER UNIT

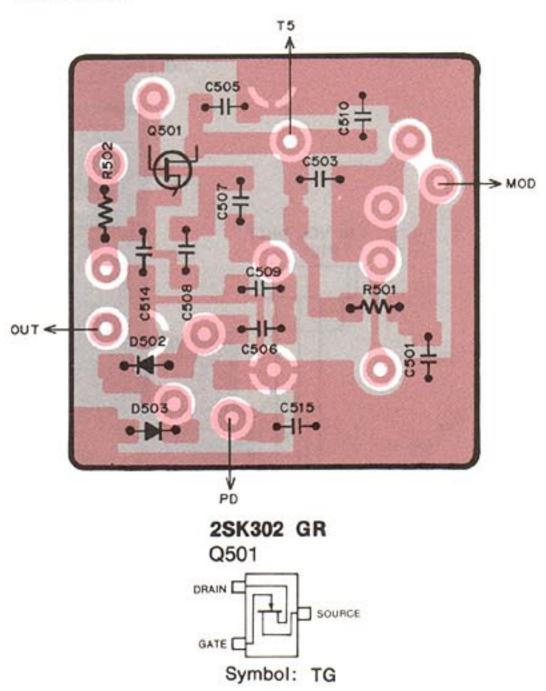
### COMPONENT SIDE



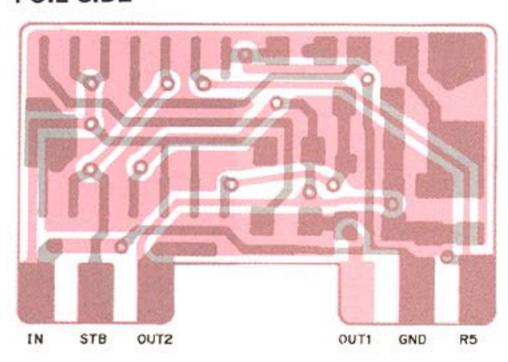
### POWER UNIT



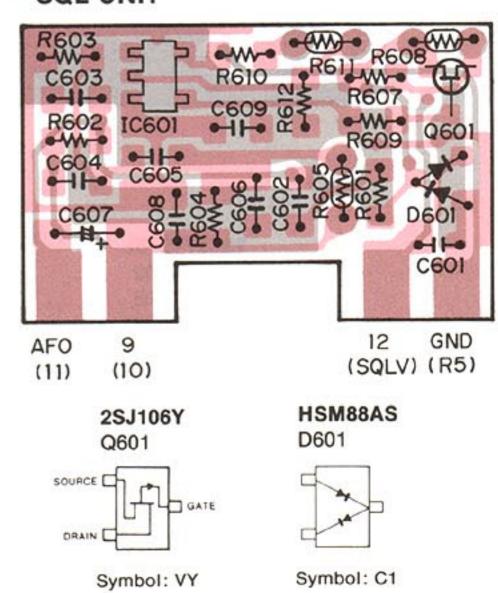
### **FOIL SIDE**



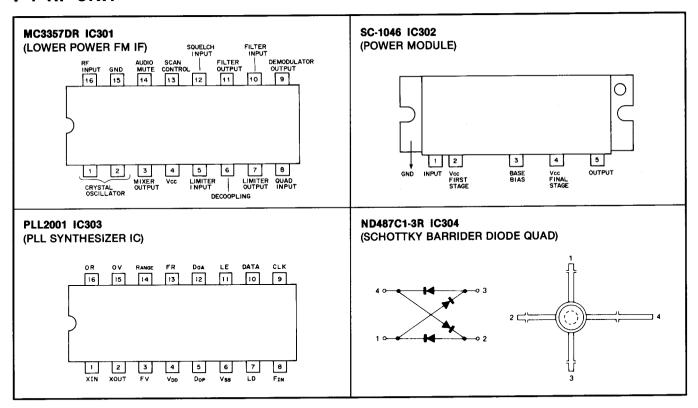
### **FOIL SIDE**



### SQL UNIT



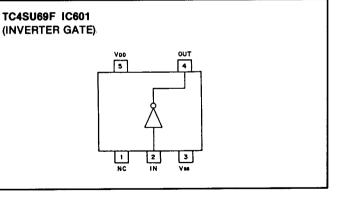
### **7-4 RF UNIT**



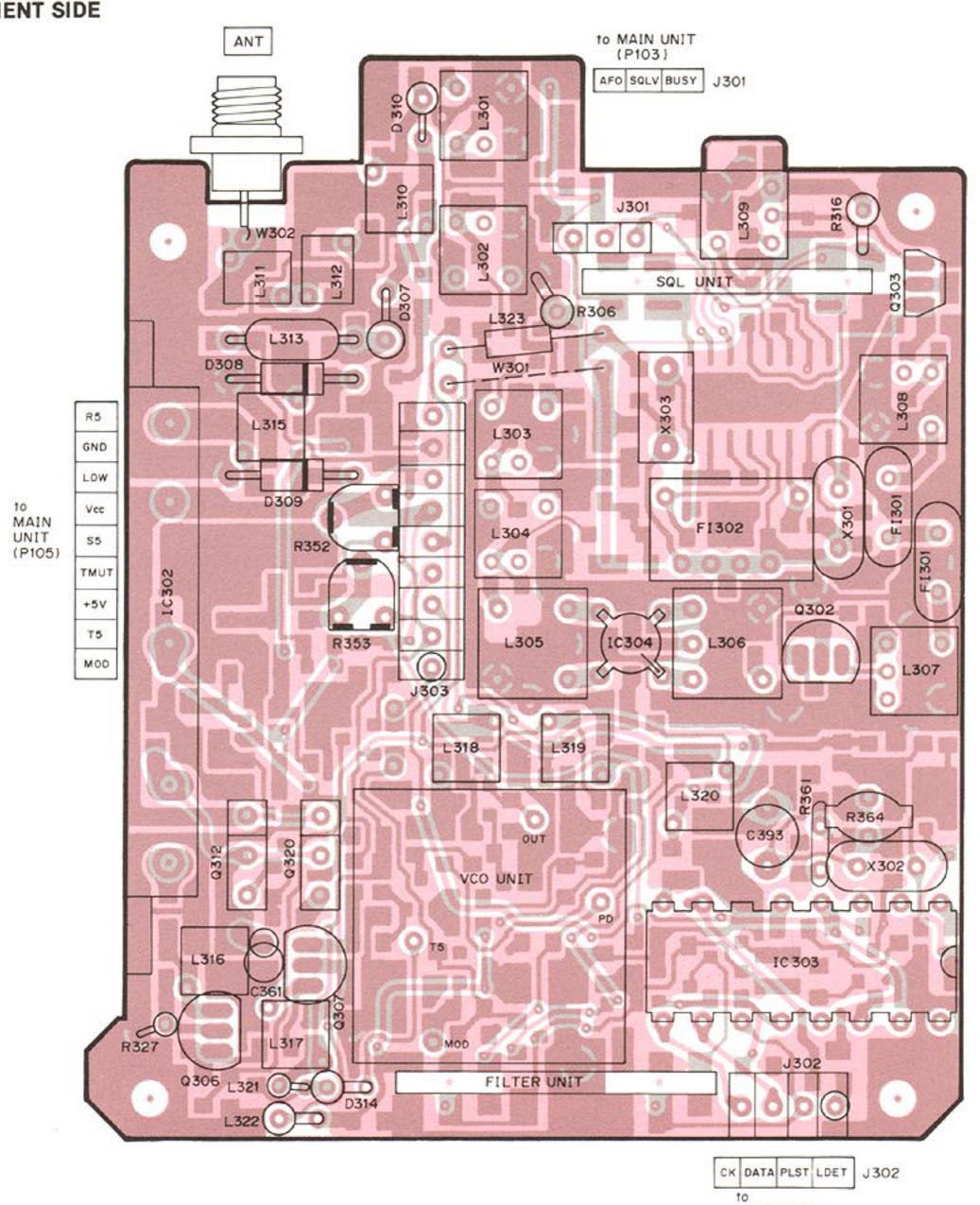
### **FILTER UNIT**

#### µРD4066BG IC701 (QUAD BILATERAL SWITCHING) CONTROL IN OUT/ OUT OUT 14 7 3 6 IN/ IN/ OUT/ OUT/ OUT CONTROL IN

### **SQL UNIT**



### COMPONENT SIDE



MAIN UNIT (P104)

2SA1162 GR

Q308, Q309

Q313, Q316

Symbol: SG

COLLECTOR

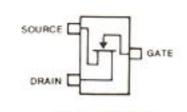
BASE

EMITTER [

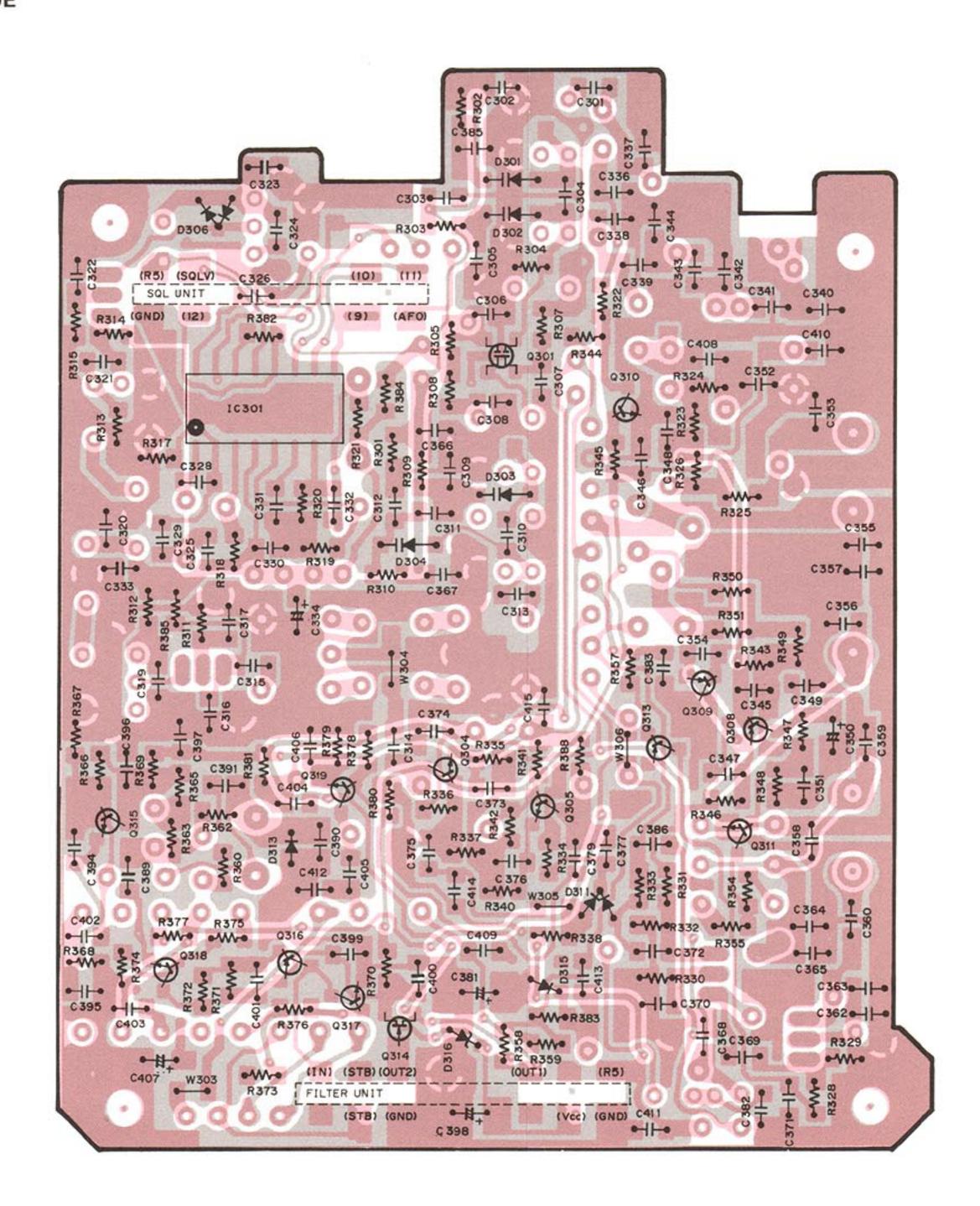
2SC3356 2SK241 K 2SC2026 3SK131 K Q303 Q304, Q305 Q302, Q306 Q301 Q319 Q307 GATES BASE [ COLLECTOR COLLECTOR EMITTER BASE EMITTER Symbol: R22 Symbol: V13

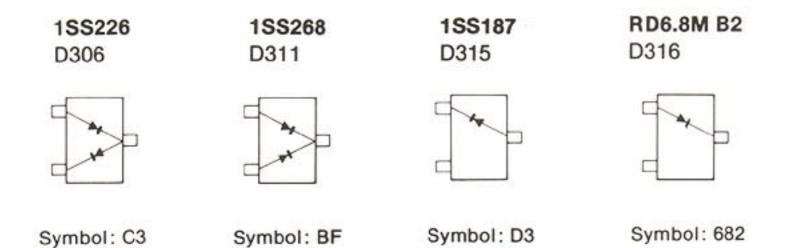
2SK209 O 2SB1237 TV2R 2SC2712 BL Q312, Q320 Q314 Q310, Q311 Q315, Q317 Q318 SOURCE \_\_ BASE [ GATE COLLECTOR COLLECTOR DRAIN EMITTER [ EMITTER

Symbol: LL



Symbol: XO





### [EF PARTS]

[EF PAR	· • ,	
REF. NO.	DESCRIPTION	PART NO.
R1	Variable Resistor	RK0971111
C1	Ceramic	0.001μF 50V
C2	Ceramic	0.001μF 50V
C4	Ceramic	0.001μF 50V 470pF 50V
J1	Connector	TNC-R107
J2	Connector	PI28A04M
J3	Connector	RT-01T-1.0B
P1	Connector	PI28A04F
P2	Connector	SMF-01T-1.0
F1	Fuse	MC2 1/2
DS1	LED	TLSG222
DS2	LED	TLSG222
MC1	Microphone	KUC-2023-01-006
S1	Switch	KSR16-0-18
S2 S3	Switch Switch	MS-243 2P MS-243 2P
SP1	Speaker	40P-177B
EP1	P.C. Board	B-1702B (POWER UNIT)
EP2	P.C. Board	B-1703A (VOL UNIT)
EP3 EP4	P.C. Board P.C. Board	B-1704B (LED UNIT) B-1705B (LOGIC-EF)
W1	Wire	13/02/140/W01/B30
W2	Wire	24/04/050/D02/W01
W3	Wire	24/01/050/D02/W01
W4	Wire	24/03/100/D02/W01
W5	Wire	24/00/080/D02/W01
	i	

### [LOGIC UNIT]

REF. NO.	DESCRIPTION	PART NO.	
IC801	ıc	μPD75306GF-015-3B9	
IC802	IC	S-8054ALB-LM-T	
Q801	Transistor	2SC3395	
Q802	Transistor	2SA1362 GR	
Q803	Transistor	2SC2712 BL	
Q804	Transistor	2SC3395	
Q805	Transistor	2SA1162 GR	
Q806	Transistor	2SC3395	
Q807	Transistor	2SC3395	
Q808	Transistor	2SC3395	
Q809	Transistor	2SC3395	

### **ILOGIC UNITI**

[LOGIC	[דואט		
REF. NO.	DESCRIPTION	PAR	T NO.
Q810	Transistor	2SA1341	
D801	Diode	1SS181	
D802	Diode	188190	
D803	Diode	1SS196	
D804	Diode	188196	
D805	Diode	188184	
X801	Crystal	RF4A3 F.	AC (4.19MHz)
R801	Resistor	47kΩ	MCR10
R802	Resistor	47kΩ	MCR10
R803	Resistor	47kΩ	MCR10
R804	Resistor	47kΩ 47kΩ	MCR10 MCR10
R805 R806	Resistor Resistor	47kΩ 47kΩ	MCR10 MCR10
R807	Resistor	1ΜΩ	MCR10
R808	Resistor	1ΜΩ	MCR10
R809	Resistor	47kΩ	MCR10
R810	Resistor	47kΩ	MCR10
R811	Resistor	47kΩ	MCR10
R812	Resistor	47kΩ	MCR10
R813	Resistor	470Ω	MCR10
R814	Resistor	470Ω	MCR10
R815 R816	Resistor Resistor	470Ω 22kΩ	MCR10 MCR10
R817	Resistor	100kΩ	MCR10
R818	Resistor	47kΩ	MCR10
R819	Resistor	1ΜΩ	MCR10
R820	Resistor	1kΩ	MCR10
R821	Resistor	100kΩ	MCR10
R822	Resistor	1ΜΩ	MCR10
R823	Resistor	100kΩ	MCR10
R827 R828	Resistor Resistor	47kΩ 1MΩ	MCR10 MCR10
R829	Resistor	220kΩ	MCR10
C801	Ceramic	0.01µF	GRM40 B
C802	Tantalum	TESVD0J4	476M-12L
C803	Ceramic	0.01μF	GRM40 B
C804	Ceramic	15pF	GRM40 CH
C805	Ceramic	15pF	GRM40 CH
C806	Ceramic	0.001µF	GRM40
C807 C808	Ceramic Ceramic	0.001µF	GRM40 GRM40 B
C809	Ceramic	0.001µF	GRM40 B
C810	Ceramic	0.001μF	GRM40 B GRM40 B
J801	Connector	SLEM12R	-2
S801	Switch	SKH HLB	0001 (CLONE)
BT801	Lithium Battery	BR2032-IF	lF
EP801	P.C. Board	B-1664C (	LOGIC UNIT)
W801 W802	Jumper Jumper	MCR10-JF MCR10-JF	1

# [MAIN UNIT]

REF. NO.	DESCRIPTION	PART NO.		
IC101	IC	BA4558F		
IC102	ic	LM386N-3		
IC103	IC	μPD4094BG		
IC104	IC	MN6520		
į				
Q101	Transistor	2SC2712 BL		
Q101	Transistor	2SC2712 BL		
Q102	Transistor	2SA1162 GR		
Q104	Transistor	2SA1162 GR		
Q105	Transistor	2SA1162 GR		
Q106	Transistor	2SC2712 BL		
Q107	Transistor	2SB909M R 2SC2712 BL		
Q108 Q109	Transistor FET	2SJ106 Y		
Q110	Transistor	2SC2712 BL		
Q111	Transistor	2SB909M R		
Q112	Transistor	2SC2712 BL		
Q113	Transistor	2SB909M R		
Q114	Transistor	2SC2712 BL		
Q115 Q116	Transistor Transistor	2SB909M R 2SA1162 GR		
Q116 Q117	Transistor	2SA1162 GR		
Q117 Q118	Transistor	2SB909M R		
Q119	Transistor	2SC2712 BL		
Q120	Transistor	2SC2712 BL		
Q121	Transistor	2SC2712 BL		
D101	Diode	1SS226		
D102	Diode	1SS184		
D103	Diode	1SS184		
D104	Zener	RD4.7MB3		
D105	Diode	1SS184		
D106 D108	Diode Diode	DWA010 1SS184		
D109	Diode	1SS184		
D110	Diode	1SS190		
D111	Diode	1SS181		
D112	Zener	RD5.1JS B2		
V404	Caratal	RF4A3 FAC (4.194MHz)		
X101	Crystal	HF4A3 FAU (4.194MHZ)		
R101	Resistor	33kΩ MCR10		
R102	Resistor	560Ω MCR10		
R103	Resistor	180kΩ MCR10		
R104	Trimmer	330kΩ RH04A3AN5J		
R105	Resistor	180kΩ MCR10 1kΩ MCR10		
R106 R107	Resistor Resistor	1kΩ MCR10 180kΩ MCR10		
R108	Resistor	120kΩ MCR10		
R109	Resistor	220kΩ MCR10		
R110	Resistor	82kΩ MCR10		
R111	Resistor	82kΩ MCR10		
R112 R113	Resistor Resistor	1.2kΩ MCR10 3.9kΩ MCR10		
R113	Resistor	390kΩ MCR10		
R115	Resistor	1MΩ MCR10		
R116	Trimmer	47kΩ RH04A3AS4J		
R117	Resistor	15kΩ MCR10		
R118	Trimmer	330kΩ RH04A3AN5J 100kΩ MCR10		
R119 R120	Resistor Resistor	27kΩ MCR10		
R120	Resistor	47kΩ MCR10		
R122	Resistor	1kΩ MCR10		
R123	Resistor	47kΩ MCR10		
R124	Resistor	56kΩ MCR10		
R125 R126	Resistor Resistor	1kΩ MCR10 27Ω MCR10		
R126	Resistor	5.6kΩ MCR10		
R128	Resistor	47kΩ MCR10		
R129	Resistor	47kΩ MCR10		
R130	Resistor	1kΩ MCR10		

REF. NO.	DESCRIPTION	PART	NO.
R131	Resistor	1.8kΩ	MCR10
R132	Resistor	150kΩ	MCR10
R133 R134	Resistor Resistor	820Ω 6.8kΩ	MCR10 MCR10
R135	Resistor	1.5ΜΩ	MCR10
R136	Resistor	470kΩ	MCR10
R137	Resistor	33kΩ	MCR10
R138 R140	Resistor Resistor	1ΜΩ 1ΜΩ	MCR10 MCR10
R141	Resistor	1ΜΩ	MCR10
R142	Resistor	12kΩ	MCR10
R143	Resistor Resistor	330Ω 12kΩ	MCR10 MCR10
R144 R145	Resistor	1.2kΩ	MCR10
R146	Resistor	10kΩ	MCR10
R147	Resistor	470Ω 47kΩ	MCR10 MCR10
R148 R149	Resistor Resistor	47 KΩ 56kΩ	MCR10
R150	Resistor	47kΩ	MCR10
R151	Resistor	1.2kΩ	MCR10
R152	Resistor Resistor	47kΩ 10kΩ	MCR10 MCR10
R153 R154	Resistor	10kΩ 12kΩ	MCR10
R155	Resistor	10kΩ	MCR10
R156	Resistor	820kΩ	MCR10
R158 R159	Resistor Resistor	10kΩ 10kΩ	MCR10
R160	Trimmer	47kΩ	RH04A3AS4J
R161	Resistor	1kΩ	MCR10
R163	Resistor	47kΩ	MCR10
R164 R165	Resistor Resistor	47kΩ 15kΩ	MCR10 MCR10
R166	Resistor	10kΩ	MCR10
R167	Resistor	1kΩ	MCR10
R168	Resistor	10kΩ	MCR10 MCR10
R169 R170	Resistor Resistor	6.8kΩ 10kΩ	MCR10
R171	Resistor	180kΩ	MCR10
R172	Resistor	33kΩ	MCR10
R173 R174	Resistor Resistor	10kΩ 10kΩ	MCR10 MCR10
R175	Resistor	6.8kΩ	MCR10
R177	Resistor	470kΩ	MCR10
R181	Resistor	33kΩ 120kΩ	MCR10 MCR10
R182 R184	Resistor Resistor	120KΩ	MCR10
R185	Resistor	56kΩ	MCR10
R186	Resistor	4.7kΩ	MCR10
R187 R188	Resistor Resistor	100kΩ 10Ω	MCR10 MCR10
N100	nesistoi	1052	MORTO
C101	Ceramic	470pF	GRM40
C102	Ceramic	0.001μF 0.01μF	GRM40 GRM40 F
C103 C104	Ceramic Tantalum	0.01μF 0.1μF	35V SV
C105	Ceramic	0.001μF	GRM40
C106	Ceramic	0.001μF	GRM40
C107 C108	Ceramic Ceramic	0.001µF 0.001µF	GRM40 GRM40
C108	Ceramic	0.001μ1 0.0022μF	GRM40
C110	Ceramic	470pF	GRM40
C111	Ceramic	100pF 0.001μF	GRM40 CH GRM40
C112 C113	Ceramic Tantalum	0.001μF 2.2μF	TEMSVA1C225M-8L
C114	Ceramic	0.1μF	GRM40 F
C115	Tantalum	2.2μF	TEMSVA1C225M-8L
C116 C117	Ceramic Ceramic	0.1μF 0.1μF	GRM40 F GRM40 F
C118	Ceramic	0.1μF	GRM40 F
C119	Ceramic	0.001μF	GRM40
C120	Ceramic Ceramic	0.1μF 0.0068μF	GRM40 F GRM40
C121 C122	Ceramic	0.0068μF	GRM40
C123	Ceramic	47pF	GRM40
<u> </u>			

### [MAIN UNIT]

[MAIN U	NIT]	
REF. NO.	DESCRIPTION	PART NO.
C124	Ceramic	47pF GRM40
C125	Ceramic	47pF GRM40
C126 C127	Electrolytic Electrolytic	100μF 6.3V RC3 10μF 16V RC3
C127	Tantalum	2.2µF TEMSVA1C225M-8L
C129	Ceramic	0.001μF GRM40
C130	Electrolytic	1μF 50V RC3
C131 C132	Tantalum Ceramic	1μF 16V SV 0.001μF GRM40
C132	Ceramic	0.1µF GRM40 F
C134	Ceramic	0.0068μF GRM40
C135	Ceramic	0.0047µF GRM40
C136 C137	Ceramic Electrolytic	0.01μF GRM40 F 47μF 6.3V RC3
C138	Ceramic	0.1μF GRM40 F
C139	Ceramic	0.001μF GRM40
C140	Ceramic	0.1μF GRM40 F 0.001μF GRM40
C141 C142	Ceramic Tantalum	0.001μF GRM40 0.47μF TEMSVA1V474M-8L
C143	Ceramic	0.001μF GRM40
C144	Electrolytic	10μF 16V RC3
C145 C146	Ceramic Ceramic	0.001μF GRM40 0.1μF GRM40 F
C146	Ceramic	0.01μF GRM40 F
C148	Electrolytic	22μF 16V RC3
C149	Ceramic	18pF GRM40 CH 18pF GRM40 CH
C150 C151	Ceramic Ceramic	18pF GRM40 CH 0.001μF GRM40
C152	Electrolytic	47μF 6.3V RC3
C153	Ceramic	0.1μF GRM40 F
C154	Ceramic	0.001μF GRM40 22μF 16V RC3
C155 C156	Electrolytic Electrolytic	47μF 6.3V RC3
C158	Electrolytic	47μF 6.3V RC3
C159	Ceramic	0.001μF GRM40
C160 C161	Ceramic Ceramic	470pF GRM40 0.001μF GRM40
C162	Electrolytic	22μF 16V RC3
C163	Electrolytic	47μF 16V MS5
C164	Ceramic	0.001μF GRM40 3.3μF 6.3V SV
C165 C166	Tantalum Tantalum	0.47μF 35V DN
C167	Ceramic	0.1μF GRM40 F
C168	Ceramic	0.0047μF GRM40
C169 C170	Tantalum Ceramic	4.7μF 16V DN 470pF GRM40
C171	Ceramic	0.001μF GRM40
C172	Ceramic	0.01μF GRM40 F
C174 C175	Ceramic Ceramic	0.01μF GRM40 F 0.001μF GRM40
C176	Ceramic	0.001µF GRM40
C177	Ceramic	0.001μF GRM40
C178	Ceramic	0.1μF GRM40 F
J101	Connector	PI28A05M
J102	Connector	PI28A04M
J103 J104	Connector Connector	HSJ-1102-01-540 HSJ-0836-01-010
0.04		
P101	Connector	PI28A04F
P103 P104	Connector Connector	BB04A03F BB04A04F
P105	Connector	BB04A09F
S101	Switch	SKHHLP000 (PTT)
EP101 EP104	P.C. Board F.P.C.	B-1665C (MAIN UNIT) B-1710 (LOGIC-MAIN)

## [MAIN UNIT]

V101 Wire 24/03/040/D02/C21	
V102 Wire 24/01/055/D02/C21	
V103 Wire 23/02/065/D02/C21	
V104 Wire 24/00/080/D02/C21	
V105 Jumper MCR10-JPW	
V106 Jumper MCR10-JPW	
V107 Jumper MCR10-JPW	
V108 Jumper MCR10-JPW	
VIO CONTRACTOR CONTRAC	

## [RF UNIT]

REF. NO.	DESCRIPTION	PART NO.	
IC301	IC	MC3357 DR	
IC302	iC	SC-1046	
IC303	IC	PLL2001	
IC304	IC	ND487C1-3R	
Q301	FET	3SK131 K	
Q301 Q302	Transistor	2SC2026	
Q302 Q303	FET	2SK241 GR	
Q304	Transistor	2SC3356	
Q305	Transistor	2SC3356	
Q306	Transistor	2SC2026	
Q307	Transistor	2SC2026	
Q308	Transistor	2SA1162 GR	
Q309	Transistor	2SA1162 GR	
Q310	Transistor	2SC2712 BL	
Q311	Transistor	2SC2712 BL 2SB1237 TV2 R	
Q312	Transistor Transistor	2SA1162 GR	
Q313 Q314	FET	2SK209 O	
Q314 Q315	Transistor	2SC2712 BL	
Q316	Transistor	2SA1162 GR	
Q317	Transistor	2SC2712 BL	
Q318	Transistor	2SC2712 BL	
Q319	Transistor	2SC3356	
Q320	Transistor	2SB1237 TV2 R	
D301	Varicap	MA334 B	
D302	Varicap	MA334 B	
D303	Varicap	MA334 B	
D304	Varicap	MA334 B	
D306	Diode	1SS226	
D307	Diode	1SS265	
D308	Diode	1SS97	
D309	Diode	1SS97 1SS265	
D310 D311	Diode Diode	1SS268	
D311	Varicap	1SV166	
D313	Diode	1SS99	
D315	Diode	1SS187	
D316	Zener	RD6.8M B2	
FI301	Crystal	FL-42	
FI301	Ceramic	CFZM455E10	
	20.0		
X301	Crystal	CR-70	
X301	Crystal	CR-212 (10MHz)	
X303	Discriminator	CDB455C7A	
L301	Coil	LS-334	
L302	Coil	LS-335	
L303	Coil	LS-336	

## [RF UNIT]

INF UNIT	· .	
REF. NO.	DESCRIPTION	PART NO.
L304	Coll	LS-335
L305	Coll Coil	LR-145
L306 L307	Coll	LR-116 LS-330
L308	Coil	LS-332
L309	Coil	LS-331
L310	Coil	LA-237
L311 L312	Coil Coil	LA-234 LA-227
L313	Coil	LAL03NA 4R7K 4.7μ
L315	Coil	LA-235
L316	Coil	LA-237 LA-237
L317 L318	Coil Coil	LA-237 LA-237
L319	Coll	LA-237
L320	Coil	LA-237
L321	Coil	LAL02NA 4R7K 4.7µ LAL02NA 4R7K 4.7µ
L322 L323	Coil Coil	LALO2NA 487K 4.7µ LALO2NA 101K 100µ
		•
R301	Resistor	47kΩ MCR10
R302	Resistor	220kΩ MCR10
R303 R304	Resistor Resistor	220kΩ MCR10 47kΩ MCR10
R304	Resistor	82kΩ MCR10
R306	Resistor	150kΩ ELR20
R307	Resistor	56Ω MCR10
R308 R309	Resistor Resistor	10Ω MCR10 220kΩ MCR10
R310	Resistor	220kΩ MCR10
R311	Resistor	33Ω MCR10
R312	Resistor	22Ω MCR10 4.7kΩ MCR10
R313 R314	Resistor Resistor	100kΩ MCR10
R315	Resistor	100Ω MCR10
R316	Resistor	22Ω ELR20
R317 R318	Resistor Resistor	22kΩ MCR10 1.5kΩ MCR10
R319	Resistor	1.5kΩ MCR10
R320	Resistor	47kΩ MCR10
R321 R322	Resistor Resistor	1.5kΩ MCR10 180Ω MCR10
R323	Resistor	4.7kΩ MCR10
R324	Resistor	100kΩ MCR10
R325	Resistor Resistor	100kΩ MCR10 4.7kΩ MCR10
R326 R327	Resistor	47Ω ELR20
R328	Resistor	1.2kΩ MCR10
R329	Resistor	1kΩ MCR10
R330 R331	Resistor Resistor	470Ω MCR10 5.6kΩ MCR10
R332	Resistor	4.7kΩ MCR10
R333	Resistor	10kΩ MCR10
R334	Resistor	22kΩ MCR10
R335 R336	Resistor Resistor	150Ω MCR10 22kΩ MCR10
R337	Resistor	5.6kΩ MCR10
R338	Resistor	10kΩ MCR10
R340 R341	Resistor Resistor	150Ω MCR10 5.6kΩ MCR10
R341 R342	Resistor	4.7kΩ MCR10
R343	Resistor	22kΩ MCR10
R344	Resistor	1MΩ MCR10
R345 R346	Resistor Resistor	47kΩ MCR10 82kΩ MCR10
R347	Resistor	100kΩ MCR10
R348	Resistor	270kΩ MCR10
R349 R350	Resistor Resistor	22kΩ MCR10 3.9kΩ MCR10
R351	Resistor	8.2kΩ MCR10
R352	Trimmer	22kΩ RH0421CJ4J09A
R353	Trimmer	22kΩ RH0421CJ4J09A
R354 R355	Resistor Resistor	1.5kΩ MCR10 1.5kΩ MCR10

REF. NO.	DESCRIPTION	PART	r NO.
R357	Resistor	6.8kΩ	MCR10
R358	Resistor	820kΩ	MCR10
R359	Resistor	120kΩ	MCR10 MCR10
R360 R361	Resistor Thermistor	15kΩ 33D28	MCHIU
R362	Resistor	10kΩ	MCR10
R363	Resistor	10kΩ	MCR10
R364	Thermistor	33D28	MODIO
R365 R366	Resistor Resistor	6.8kΩ 120kΩ	MCR10 MCR10
R367	Resistor	68kΩ	MCR10
R368	Resistor	2.2kΩ	MCR10
R369 R370	Resistor Resistor	100Ω 1.5kΩ	MCR10 MCR10
R371	Resistor	4.7kΩ	MCR10
R372	Resistor	10kΩ	MCR10
R373	Resistor	3.3kΩ	MCR10
R374 R375	Resistor Resistor	47kΩ 100kΩ	MCR10 MCR10
R376	Resistor	10kΩ	MCR10
R377	Resistor	10Ω	MCR10
R378 R379	Resistor	3.3kΩ 120Ω	MCR10 MCR10
R379 R380	Resistor Resistor	1.8kΩ	MCR10 MCR10
R381	Resistor	220Ω	MCR10
R382	Resistor	27kΩ	MCR10
R383 R384	Resistor Resistor	47kΩ 100Ω	MCR10 MCR10
R385	Resistor	100kΩ	MCR10
R388	Resistor	2.2kΩ	MCR10
C301	Ceramic	100pF	GRM40
C302	Ceramic	0.001μF	GRM40
C303	Ceramic	0.001μF	GRM40
C304 C305	Ceramic Ceramic	1pF 27pF	GRM40 GRM40
C306	Ceramic	0.001μF	GRM40
C307	Ceramic	0.001μF	GRM40
C308	Ceramic	0.001μF	GRM40
C309 C310	Ceramic Ceramic	27pF 0.5pF	GRM40 GRM40
C311	Ceramic	1pF	GRM40
C312	Ceramic	22pF	GRM40
C313 C314	Ceramic Ceramic	3pF 22pF	GRM40 GRM40
C314 C315	Ceramic	0.01μF	GRM40 B
C316	Ceramic	220pF	GRM40
C317	Ceramic	0.01μF	GRM40 B
C319 C320	Ceramic Ceramic	0.001μF 5pF	GRM40 GRM40
C321	Ceramic	180pF	GRM40
C322	Ceramic	0.001µF	GRM40
C323	Ceramic	0.001μF 47pF	GRM40 GRM40
C324 C325	Ceramic Ceramic	4/μF	GRM40 F
C326	Ceramic	220pF	GRM40
C328	Ceramic	120pF	GRM40
C329 C330	Ceramic Ceramic	68pF 0.022μF	GRM40 GRM40
C331	Ceramic	0.1μF	GRM40 F
C332	Ceramic	82pF	GRM40
C333	Ceramic	0.01μF	GRM40 B
C334 C336	Tantalum Ceramic	4.7μF 180pF	TEMSVA0J475M-8L GRM40
C337	Ceramic	15pF	GRM40
C338	Ceramic	15pF	GRM40
C339	Ceramic	0.001μF 12pF	GRM40 GRM40
C340 C341	Ceramic Ceramic	12pF 8pF	GRM40
C342	Ceramic	27pF	GRM40
C343	Ceramic	2pF	GRM40
C344 C345	Ceramic Ceramic	15pF 0.001μF	GRM40 GRM40
C345 C346	Ceramic	0.001μF	GRM40

#### [RF UNIT]

[RF UNI	<u> </u>		
REF. NO.	DESCRIPTION	PAR	Г NO.
C347 C348	Ceramic Ceramic	0.001μF 0.001μF	GRM40 GRM40
C349	Ceramic	0.001μF 0.001μF	GRM40
C350	Tantalum	4.7μF	TEMSVA0J475M-8L
C351	Ceramic	0.001µF	GRM40
C352 C353	Ceramic Ceramic	12pF 12pF	GRM40 GRM40
C354	Ceramic	0.001μF	GRM40
C355	Ceramic	0.001μF	GRM40
C356	Ceramic	0.001μF	GRM40
C357 C358	Ceramic Ceramic	0.1μF 0.001μF	GRM40 F GRM40
C359	Ceramic	0.001μF	GRM40
C360	Ceramic	15pF	GRM40
C361 C362	Tantalum Ceramic	2.2μF 0.001μF	16V DN GRM40
C363	Ceramic	0.001μF	GRM40 B
C364	Ceramic	0.001μF	GRM40
C365 C366	Ceramic Ceramic	0.01μF 0.001μF	GRM40 B GRM40
C367	Ceramic	0.001μF 0.001μF	GRM40 GRM40
C368	Ceramic	0.001μF	GRM40
C369	Ceramic	27pF	GRM40
C370 C371	Ceramic Ceramic	0.001μF 0.001μF	GRM40 GRM40
C372	Ceramic	2pF	GRM40
C373	Ceramic	0.001μF	GRM40
C374	Ceramic	0.001μF	GRM40
C375 C376	Ceramic Ceramic	10pF 0.001μF	GRM40 GRM40
C377	Ceramic	22pF	GRM40
C379	Ceramic	4pF	GRM40
C381 C382	Tantalum Ceramic	6.8μF 0.022μF	6.3V SV GRM40
C383	Ceramic	0.001μF	GRM40
C385	Ceramic	22pF	GRM40
C386 C389	Ceramic Ceramic	0.001μF 0.001μF	GRM40 GRM40
C390	Ceramic	5ρF	GRM40 CH
C391	Ceramic	33pF	GRM40 CH
C393 C394	Trimmer Ceramic	20pF	ECRGA020E30 GRM40
C395	Ceramic	220pF 100pF	GRM40
C396	Ceramic	0.022μF	GRM40
C397	Ceramic	0.1μF	GRM40 F
C398 C399	Tantalum Ceramic	4.7μF 0.1μF	10V SV GRM40 F
C400	Ceramic	0.001μF	GRM40
C401	Ceramic	100pF	GRM40
C402 C403	Ceramic Ceramic	0.001μF 0.1μ <del>F</del>	GRM40 GRM40 F
C404	Ceramic	0.001μF	GRM40
C405	Ceramic	33pF	GRM40
C406	Ceramic	0.001μF	GRM40
C407 C408	Tantalum Ceramic	4.7μF 0.001μF	TEMSVA0J475M-8L GRM40
C409	Ceramic	0.01μF	GRM40 B
C410	Ceramic	0.001µF	GRM40
C411 C412	Ceramic Ceramic	0.001μF 15pF	GRM40 GRM40
C413	Ceramic	470pF	GRM40
C414	Ceramic	12pF	GRM40
C415	Ceramic	0.001μF	GRM40
J301	Connector	BB04J03M	l
J302	Connector	BB04J04M	
J303	Connector	BB04J09M	1
EP301 EP307	P.C. Board Ferrite Bead	B-1666A ( DL2-OP2.6	

## [RF UNIT]

REF. NO.	DESCRIPTION	PART NO.	
W301	Jumper	JPW-01 R-01	
W302	Jumper	JPW-01 R-01	
W303	Jumper	MCR10-JPW	
W304	Jumper	MCR10-JPW	
W305	Jumper	MCR10-JPW	
W306	Jumper	MCR10-JPW	

## [VCO UNIT]

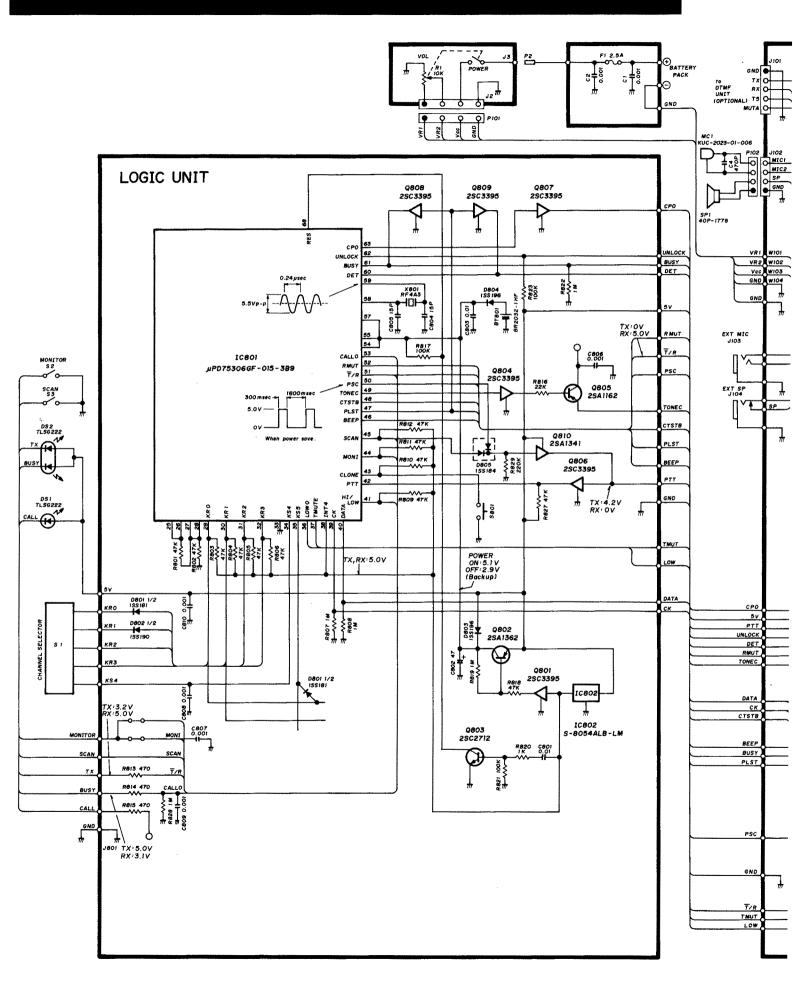
[VCO UNIT]				
REF. NO.	DESCRIPTION	PART NO.		
Q501	FET	2SK302 GR		
D501	Diode	1SS265		
D502	Varicap	1SV166 2B		
D503	Varicap	1SV166 2B		
L501	Coll	S7T-BN		
L502	Coil	LAL02NA 4R7K 4.7μ		
L503	Coil	LAL02NA 2R2M 2.2μ		
L504	Coil	LAL02NA 4R7K 4.7μ		
L505	Coil	LAL02NA 4R7K 4.7μ		
L506	Coil	LAL02NA 4R7K 4.7μ		
R501	Resistor	100kΩ MCR10		
R502	Resistor	120Ω MCR10		
C501	Ceramic	470pF GRM40		
C503	Ceramic	68pF GRM40 CH		
C505	Ceramic	68pF GRM40 CH 0.001µF GRM40 68pF GRM40 39pF GRM40		
C506	Ceramic	68pF GRM40		
C507	Ceramic	39pF GRM40		
C508	Ceramic	3pF GRM40 UJ 1pF GRM40		
C509	Ceramic	1pF GRM40		
C510	Ceramic	0.01μF GRM40 F 0.5pF 50V		
C512		0.5pF 50V		
C514	Ceramic	3pF GRM40 UJ 0.001μF GRM40		
C515	Ceramic	0.001µF GHM40		
EP501	P.C. Board	B-1670B (VCO UNIT)		

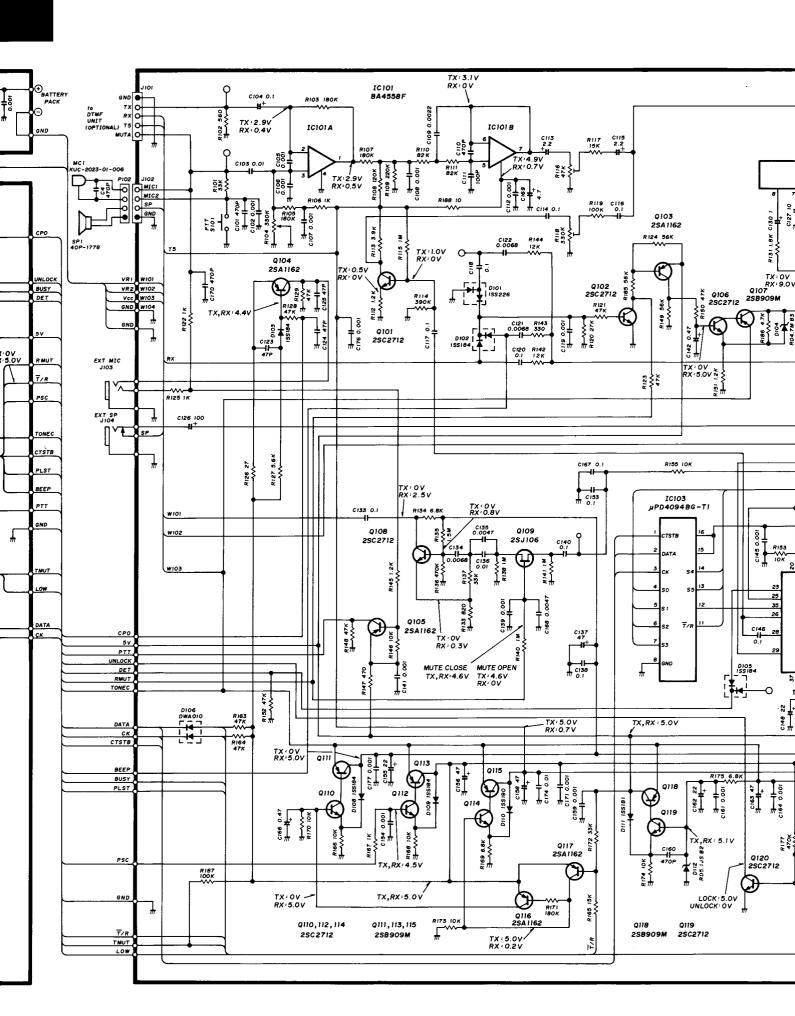
#### [SQL UNIT]

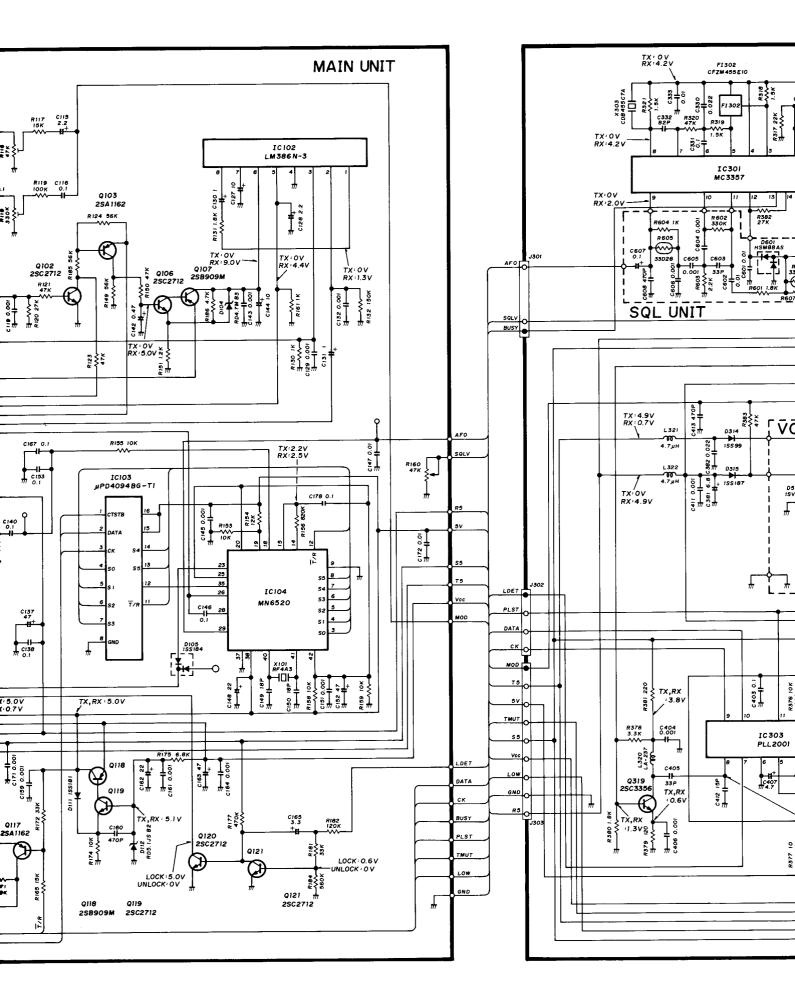
REF. NO.	DESCRIPTION	PART	NO.
IC601	IC	TC4SU69F	:
Q601	Transistor	2SJ106Y	
D601	Diode	HSM88AS	
R601	Resistor	1.8kΩ	MCR10
R602	Resistor	330kΩ	MCR10
R603	Resistor	2.2kΩ	MCR10
R604	Resistor	1.0kΩ	MCR10
R605	Thermistor	33D28	
R607	Resistor	47kΩ	MCR10
R608	Thermistor	33D28	
R609	Resistor	1ΜΩ	MCR10
R610	Resistor	4.7kΩ	MCR10
R611	Thermistor	33D28	
R612	Resistor	12kΩ	MCR10
C601	Ceramic	0.01μF	
C602	Ceramic	0.01μF	GRM40
C603	Ceramic	33pF	GRM40 CH
C604	Ceramic	0.001μF	GRM40
C605	Ceramic	0.001μF	
C606	Ceramic	0.001μF	GRM40
C607	Tantalum	0.1μF	35V SV
C608	Ceramic		GRM40
C609	Ceramic	0.001μF	GRM40
EP601	P.C. Board	B-1669B (	SQL UNIT)

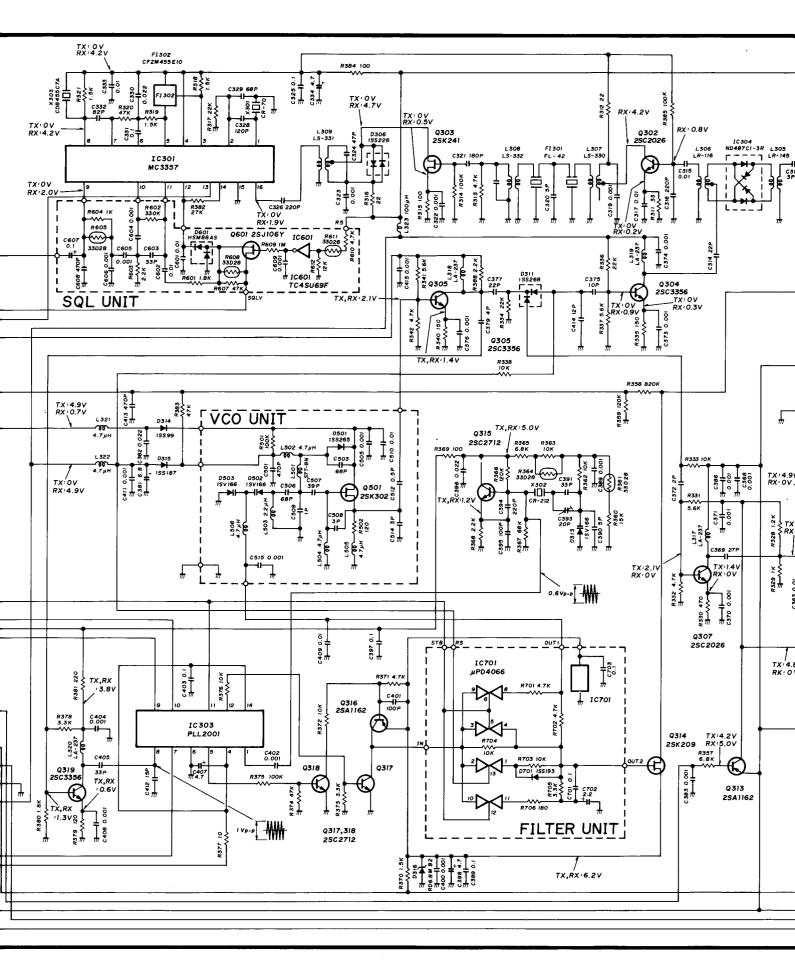
#### [FILTER UNIT]

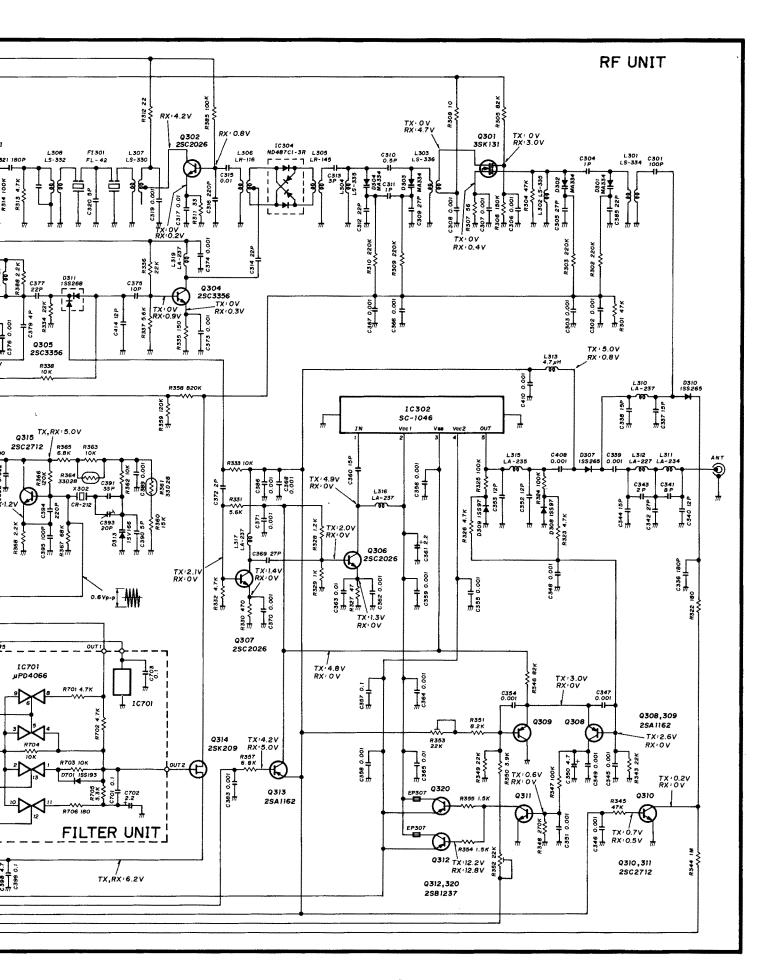
[FILTER			
REF. NO.	DESCRIPTION	PAR	T NO.
IC701	IC	μPD4066	BG
D701	Diode	188193	
R701 R702 R703 R704 R705 R706	Resistor Resistor Resistor Resistor Resistor	4.7kΩ 4.7kΩ 10kΩ 10kΩ 3.3kΩ 1kΩ	MCR10 MCR10 MCR10 MCR10 MCR10 MCR10
C701 C702 C703	Ceramic Tantalum Ceramic	0.1μF 2.2 0.1μF	GRM40 F 16V SV GRM40 F
EP701	P.C. Board	B-1596B	(FILTER UNIT)



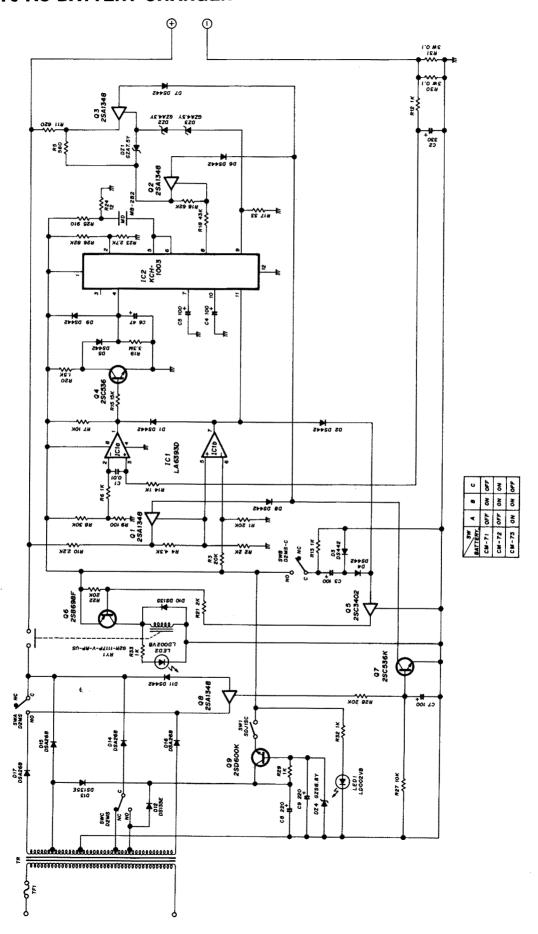




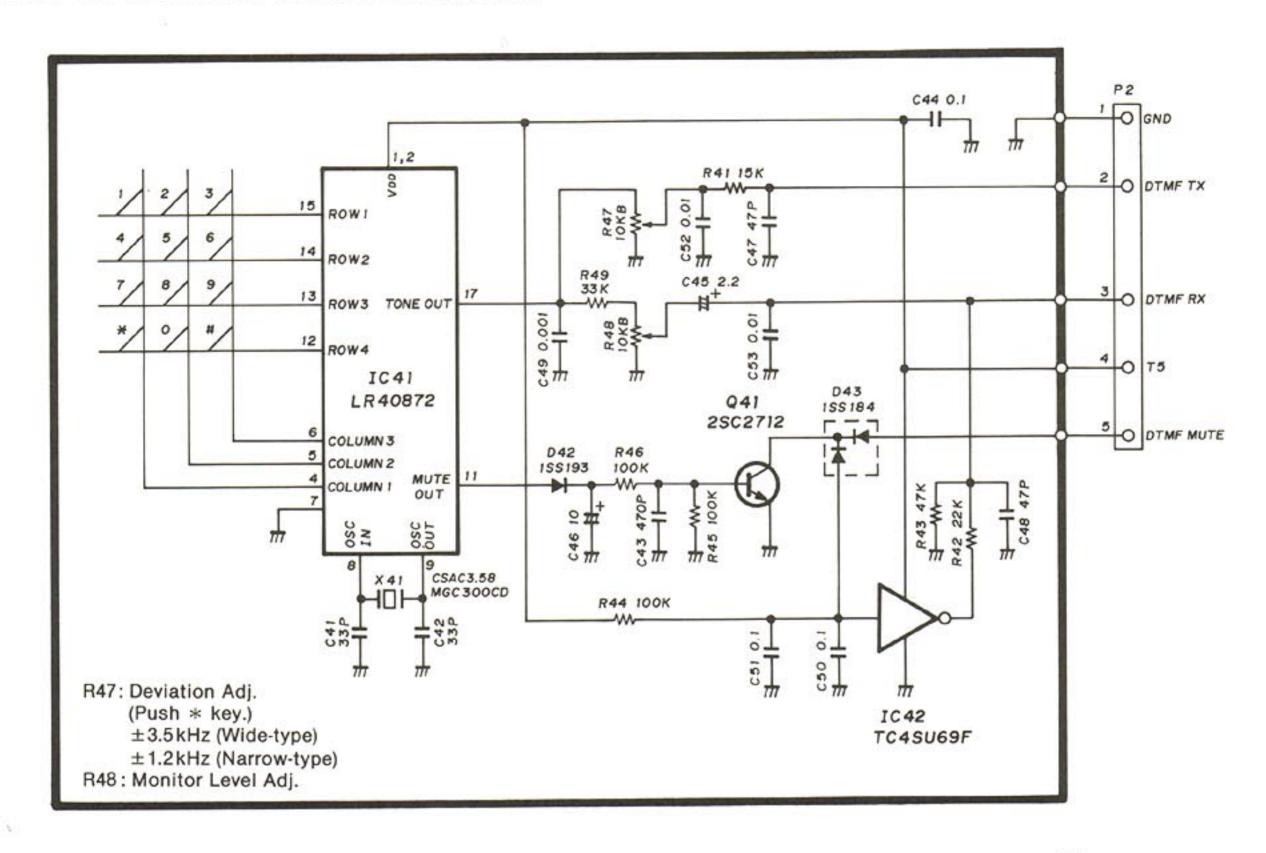


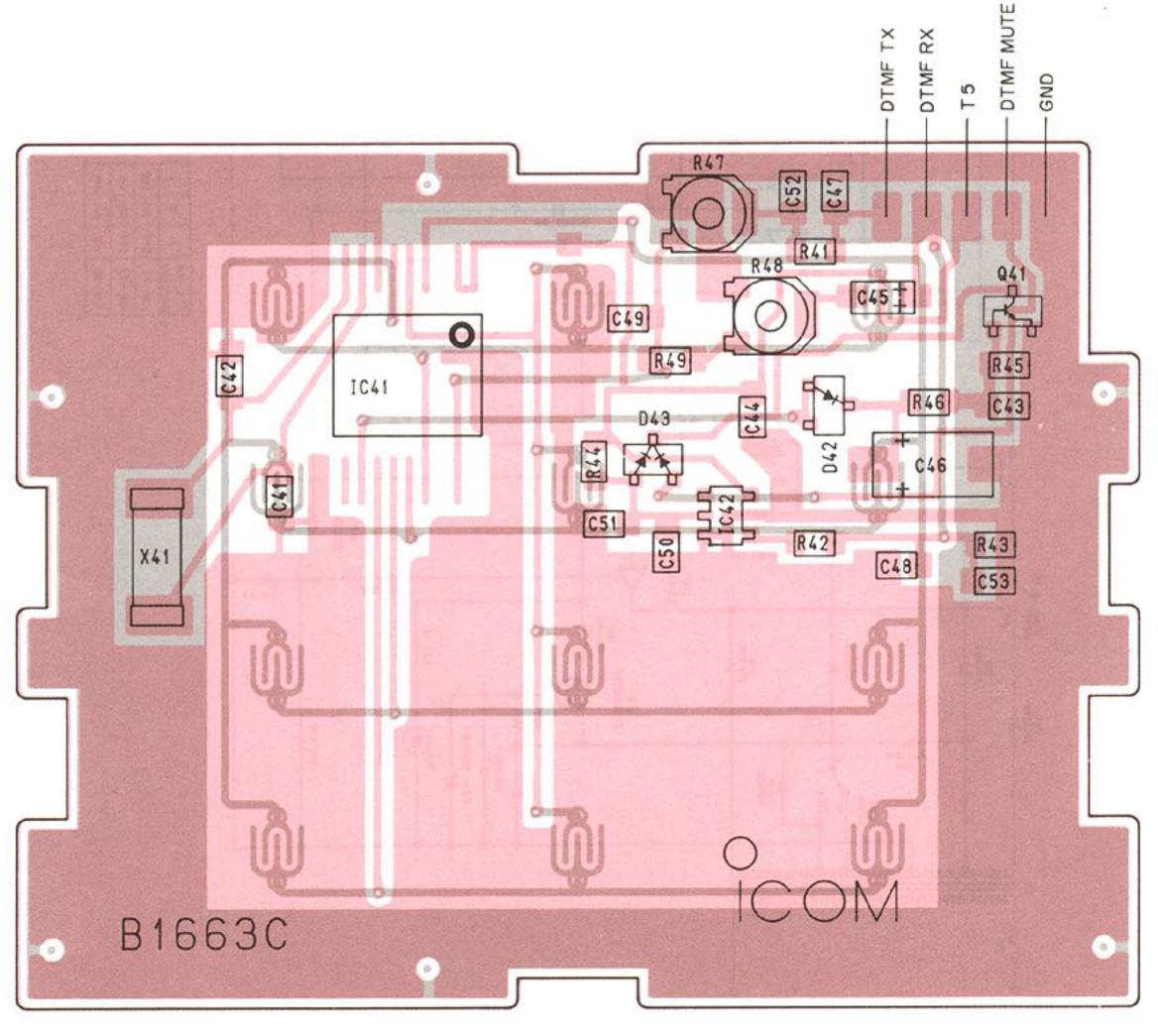


#### 10-1 BM-70 AC BATTERY CHARGER



# 10-2 UT-42 DTMF ENCODER UNIT





#### Icom Inc.

6-9-16, Kamihigashi, Hirano-ku, Osaka 547, Japan

Phone: 06 793 5301 Fax : 06 793 0013

Telex: 05277822 ICOMTR J

#### Icom America Inc.

<Corporate Headquarters>

2380 116th Avenue N.E., Bellevue, WA 98004, U.S.A.

Phone: (206) 454-8155

Fax : (206) 454-1509 Telex : 152210 ICOM AMER BVUE

<Customer Service> Phone: (206) 454-7619

<Regional Customer Service Centers> 3150 Premier Drive, Suite 126, Irving, TX 75063, U.S.A.

Phone: (214) 550-7525 Fax : (214) 550-7423

1777 Phoenix Parkway, Suite 201, Atlanta, GA 30349, U.S.A.

Phone: (404) 991-6166 Fax: (404) 991-6327

#### Icom Canada

A Division of Icom America Inc. 3071 #5 Road, Unit 9, Richmond, B.C., V6X 2T4, Canada Phone: (604) 273-7400 Fax : (604) 273-1900

#### Icom (Europe) GmbH

Communication Equipment Himmelgeister Str. 100, 4000 Düsseldorf 1, W. Germany Phone: 0211 346047

Fax : 0211 333639 Telex : 8588082 ICOM D

#### Icom (Australia) Pty. Ltd.

Incorporated In Victoria

7 Duke Street, Windsor, Victoria, 3181, Australia Phone: 03 529 7582, 03 529 8765

Fax : 03 529 8485 Telex : AA 35521 ICOM AS

#### Icom (UK) Ltd.

Unit 9, Sea St., Herne Bay, Kent, U.K.

Phone: 0227 363859 Fax : 0227 360155 Telex: 965179 ICOM G

#### Icom France S.a

120 Route de Revel, BP4063, 31029 Toulouse Cedex, France

Phone: 61, 20, 31, 49 Fax : 61, 34, 05, 91 Telex : 521515 ICOM FRA

Count	on us!		
		· · · · · · · · · · · · · · · · · · ·	
·	<u> </u>		